

## Precision, Hall-Effect Angle Sensor IC with SPI, and SENT or PWM Outputs

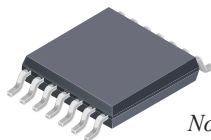
### FEATURES AND BENEFITS

- Contactless 0° to 360° angle sensor IC, for angular position and rotation direction measurement
  - Circular Vertical Hall (CVH) technology provides a single-channel sensor system, with air gap independence
- 12-bit resolution possible in Low RPM mode, 10-bit resolution in High RPM mode
- Angle Refresh Rate (output rate) configurable between 25 and 3200  $\mu$ s through EEPROM programming
  - Capable of sensing magnetic rotational speeds up to 7600 rpm, and up to 30,000 rpm with reduced accuracy
- SPI (mode 3), and SENT (Single Edge Nibble Transmission) or PWM (Pulse-Width Modulation)\*

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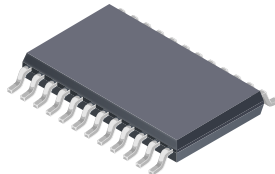
### PACKAGES:

14-pin TSSOP (Suffix LE)



Single SoC

24-pin TSSOP (Suffix LE)



Dual Independent SoCs

*Not to scale*

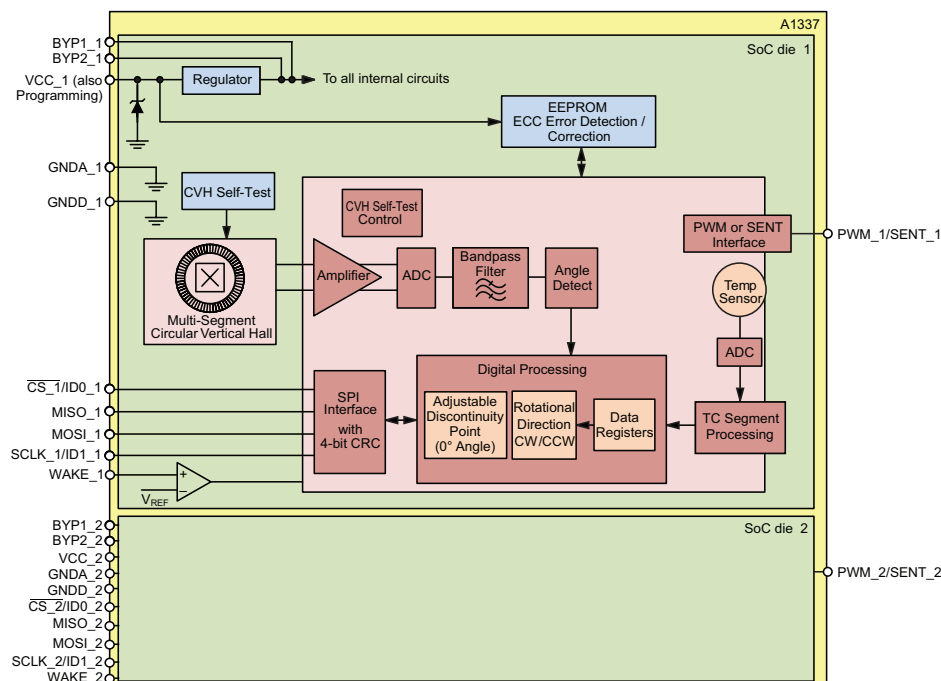
### DESCRIPTION

The A1337 is a 0° to 360° angle sensor IC that provides contactless high-resolution angular position information based on magnetic Circular Vertical Hall (CVH) technology. It has a system-on-chip (SoC) architecture that includes: a CVH front end, digital signal processing, digital SPI, and SENT or PWM outputs. It also includes on-chip EEPROM technology, capable of supporting up to 100 read/write cycles, for flexible end-of-line programming of calibration and configuration parameters. The A1337 is ideal for automotive applications requiring 0° to 360° angle measurements, such as electronic power steering (EPS), seatbelt motor position systems, rotary PRNDLs, and throttle systems.

The A1337 was designed with safety-critical application requirements in mind. It includes user-controlled, on-chip logic built-in self-test (L-BIST) and full signal path diagnostics to enable customers to determine if the IC is operating in a proper manner.

The A1337 includes integrated Turns Counter and Low-Power Mode functions. The Low-Power Mode enables the device to be connected directly to the vehicle battery and minimizes power consumption when the vehicle is in the key-off state. The Turns Counter function allows the device to keep track of either 45° or 180° turns of the motor when the part is in Low-Power Mode, monitoring the motor position even when the vehicle is in the key-off state.

*Continued on the next page...*



A1337 Magnetic Circuit and IC Diagram

## FEATURES AND BENEFITS (continued)

- SPI interface provides a robust communication protocol for fast angle readings\*
- SENT output supports four modes: SAEJ2716 (JAN2010) and Allegro proprietary options of Triggered SENT (TSENT), Sequential SENT (SSENT), and Addressable SENT (ASENT)\*
- Programmable via Manchester Encoding on the VCC line, reducing external wiring\*
- SPI and SENT interfaces allows use of multiple independent sensors for applications requiring redundancy\*
- Advanced diagnostics to support safety-critical applications, including:
  - On-chip, user-controlled logic built-in self-test (L-BIST) and signal path diagnostics
  - 4-bit CRC on SPI messages
  - User-Programmable Missing Magnet Error flag for notifying controller of low magnetic field level
- Diagnostics are initiated over the SPI or SENT interface and can directly test proper operation of the IC in safety-critical applications
- Integrated Turns Counter tracks magnet rotation in CW/CCW direction from –1280 to +1280 counts, even when vehicle is in key-off state
  - Count updates are user-selectable to be every 180° or every 45° degree of magnet rotation
  - WAKE pin for external wake-up trigger can be used to automatically detect motion > 100 rpm
- Low-Power Mode enables direct connection to vehicle battery
  - User-programmable duty cycle optimizes low-power mode current consumption (typically 85  $\mu$ A per die)
  - Ultralow-power Transport mode
- EEPROM with Error Correction Control (ECC) configuration, sensor calibration including end-of line adjustments like programmable angle reference (0°) position and rotation direction (CW or CCW)
- Available in both single-die and dual-die configurations
  - Dual-die devices contain two independent die housed within a single package
- Absolute maximum  $V_{CC}$  of 26.5 V for increased robustness and direct connection to automotive vehicle battery

\* See Selection Guide for more details.

## DESCRIPTION (continued)

The A1337 supports a Low RPM mode for slower rate applications and a High RPM mode for high-speed applications. High RPM mode is for applications that require higher refresh rates to minimize error due to latency. Low RPM mode is for applications that require higher resolution operating at lower angular velocities.

The A1337 is available in a single-die 14-pin TSSOP and a dual-die 24-pin TSSOP. Both packages are lead (Pb) free with 100% matte-tin leadframe plating.



## SELECTION GUIDE

Part Number	System Die	Output Protocols	Package	Packing [1]
A1337LLETR-DD-T	Dual	SPI and SENT	24-pin TSSOP	4000 pieces per 13-in. reel
A1337LLETR-P-DD-T	Dual	SPI and PWM	24-pin TSSOP	4000 pieces per 13-in. reel
A1337LLETR-T	Single	SPI and SENT	14-pin TSSOP	4000 pieces per 13-in. reel
A1337LLETR-P-T	Single	SPI and PWM	14-pin TSSOP	4000 pieces per 13-in. reel

[1] Contact Allegro for additional packing options.

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## SPECIFICATIONS

### ABSOLUTE MAXIMUM RATINGS

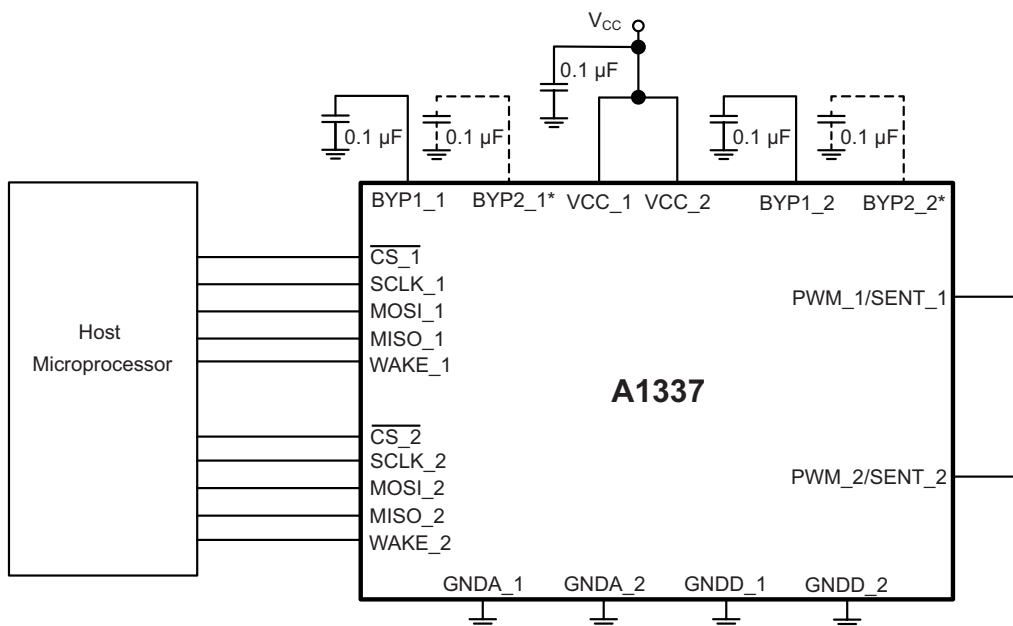
Characteristic	Symbol	Notes	Rating	Unit
Forward Supply Voltage	$V_{CC}$	Not sampling angles	26.5	V
Reverse Supply Voltage	$V_{RCC}$	Not sampling angles	-18	V
Forward WAKE Pin Voltage [1]	$V_{WAKEmax}$	Maintain nominal WAKE pin threshold levels ( $V_{WAKE(LOTH)}$ and $V_{WAKE(HITH)}$ )	2.0	V
All Other Pins Forward Voltage	$V_{IN}$		5.5	V
All Other Pins Reverse Voltage	$V_R$		0.5	V
Operating Ambient Temperature	$T_A$	L range	-40 to 150	°C
Maximum Junction Temperature	$T_{J(max)}$		165	°C
Storage Temperature	$T_{stg}$		-65 to 170	°C

[1] Sustained high temperature exposure of the WAKE pin to large voltages may result in downward shifts of  $V_{WAKE(LOTH)}$  and  $V_{WAKE(HITH)}$ . Restricting voltages from exceeding  $V_{WAKEmax}$  minimizes the likelihood of such shifts. Operation with WAKE voltages below 0.55 V prevents all occurrences. Short duration exposure to voltages between 0.55 V and  $V_{WAKEmax}$  will not result in significant shifts.

### THERMAL CHARACTERISTICS: May require derating at maximum conditions; see application information

Characteristic	Symbol	Test Conditions [2]	Value	Unit
Package Thermal Resistance	$R_{\theta JA}$	LE-24 package	117	°C/W
		LE-14 package	82	°C/W

[2] Additional thermal information available on the Allegro website.



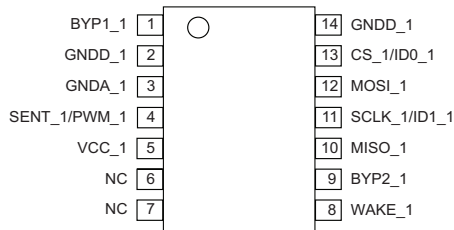
### Typical Application Diagram (dual-die version)

Either or both internal SoCs can be operated simultaneously.

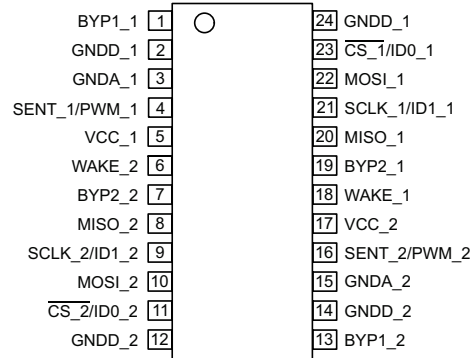
(See "EMC Reduction" Section for application circuits that require a higher level of EMC immunity.)

\* Secondary bypass capacitors only required when using Elevated SPI Output Voltage. Contact Allegro for availability.

## PINOUT DIAGRAMS AND TERMINAL LIST



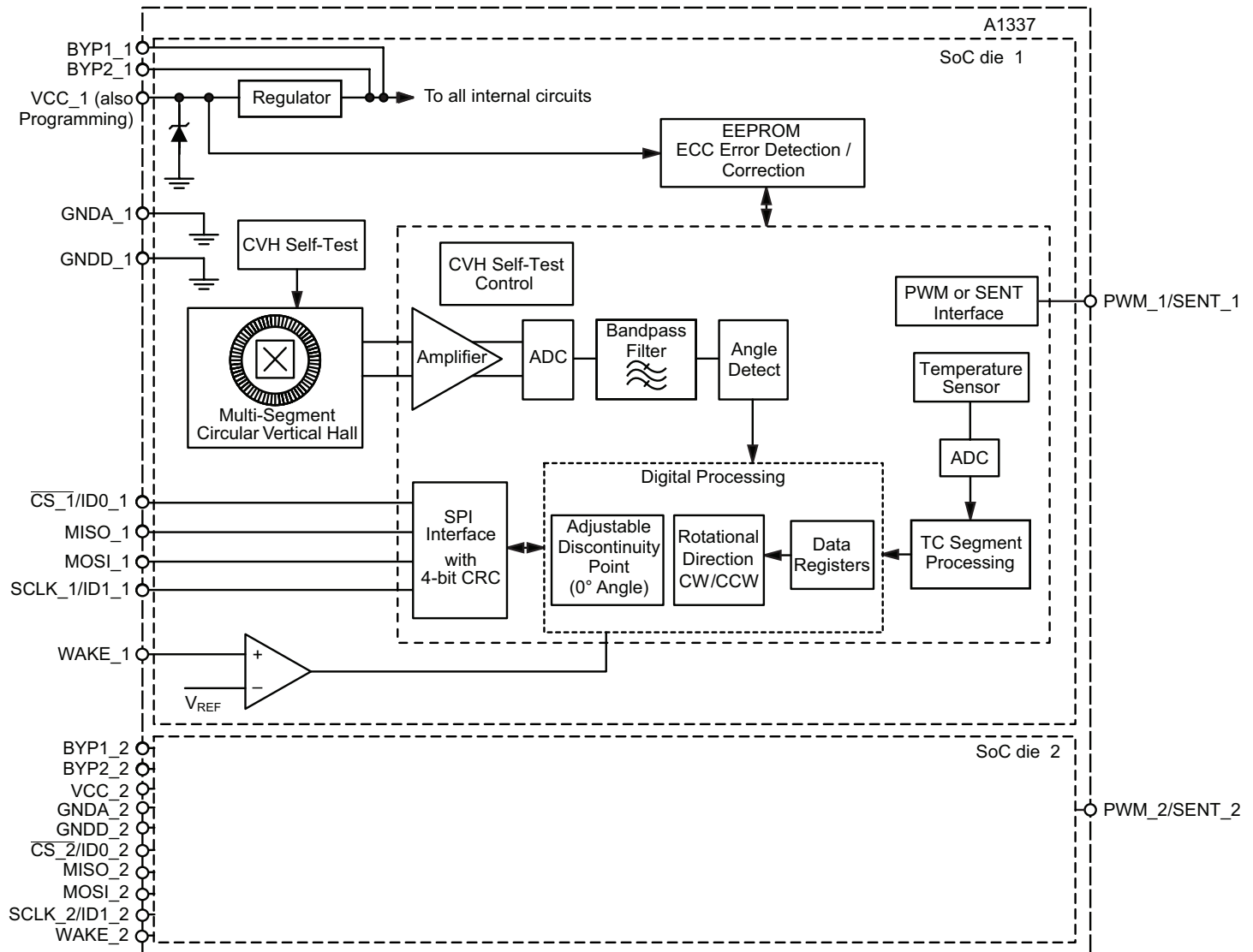
14-Pin TSSOP LE Package Pinouts



24-Pin TSSOP LE Package Pinouts

Terminal List Table

Pin Name	Pin Number		Function
	LE-14	LE-24	
BYP1_1	1	1	External Bypass Capacitor Terminal for Internal Regulator (die 1)
BYP2_1	9	19	External Bypass Capacitor Terminal for Internal Regulator (die 1)
BYP1_2	–	13	External Bypass Capacitor Terminal for Internal Regulator (die 2)
BYP2_2	–	7	External Bypass Capacitor Terminal for Internal Regulator (die 2)
CS_1/ID0_1	13	23	Option 1: SPI Chip Select Terminal, Active Low Input (die 1) Option 2: ID0 bit to indicate Slave Address for SSENT or ASENT communication modes only (die 1)
CS_2/ID0_2	–	11	Option 1: SPI Chip Select Terminal, Active Low Input (die 2) Option 2: ID0 bit to indicate Slave Address for SSENT or ASENT communication modes only (die 2)
GNDA_1	3	3	Device Analog Ground Terminal (die 1)
GNDA_2	–	15	Device Analog Ground Terminal (die 2)
GNDD_1	2, 14	2, 24	Device Digital Ground Terminal (die 1)
GNDD_2	–	12, 14	Device Digital Ground Terminal (die 2)
MISO_1	10	20	SPI Master Input/Slave Output (die 1)
MISO_2	–	8	SPI Master Input/Slave Output (die 2)
MOSI_1	12	22	SPI Master Output Slave Input (die 1)
MOSI_2	–	10	SPI Master Output Slave Input (die 2)
SCLK_1/ID1_1	11	21	Option 1: SPI Clock Terminal (die 1) Option 2: ID1 bit to indicate Slave Address for SSENT or ASENT communication modes only (die 1)
SCLK_2/ID1_2	–	9	Option 1: SPI Clock Terminal (die 2) Option 2: ID1 bit to indicate Slave Address for SSENT or ASENT communication modes only (die 2)
SENT_1/PWM_1	4	4	SENT Output (Die1); PWM Output (Die1); SENT for A1337LLETR-DD-T, A1337LLETR-T; PWM for A1337LLETR-P-DD-T, A1337LLETR-P-T
SENT_2/PWM_2	–	16	SENT Output (Die2); PWM Output (Die2); SENT for A1337LLETR-DD-T, A1337LLETR-T; PWM for A1337LLETR-P-DD-T, A1337LLETR-P-T
WAKE_1	8	18	External Wake-up Signal Input (die 1)
VCC_1	5	5	Power Supply (die 1); also used for EEPROM Programming
VCC_2	–	17	Power Supply (die 2); also used for EEPROM Programming
WAKE_2	–	6	External Wake-Up Signal Input (die 2)
NC	6, 7	–	Not internally connected; tie to GNDD



Functional Block Diagram

**OPERATING CHARACTERISTICS: Valid over the full operating voltage and ambient temperature ranges, unless otherwise noted**

Characteristics	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Unit [2]
<b>ELECTRICAL CHARACTERISTICS</b>						
Supply Voltage	$V_{CC}$		3.7	–	16	V
Normal Mode Supply Current	$I_{CC(AWAKE)}$	Each die, $T_A = 150^\circ\text{C}$	–	8.25	10	mA
Low-Power Mode Average Supply Current	$I_{CC(LP)}$	Each die, target RPM = 0, $T_A = 25^\circ\text{C}$ , 98 ms sleep time	–	55	–	$\mu\text{A}$
		Each die, A1337 in Transport Mode, $T_A = 150^\circ\text{C}$	–	30	–	$\mu\text{A}$
Undervoltage Lockout Threshold Voltage [3]	$V_{UVLOHI}$	Maximum $V_{CC}$ , $dV/dt = 1\text{ V/ms}$ , $T_A = 25^\circ\text{C}$	–	–	3.6	V
	$V_{UVLOLOW}$	Maximum $V_{CC}$ , $dV/dt = 1\text{ V/ms}$ , $T_A = 25^\circ\text{C}$	2.9	–	–	V
VCC Low Flag Threshold [4]	$V_{UVLOTH}$		3.5	–	3.9	V
Supply Zener Clamp Voltage	$V_{ZSUP}$	$I_{CC} = I_{CC(AWAKE)} + 3\text{ mA}$ , $T_A = 25^\circ\text{C}$	26.5	40	–	V
Reverse-Battery Current	$I_{RCC}$	$V_{RCC} = -18\text{ V}$ , $T_A = 25^\circ\text{C}$	–5	–	0	mA
Power-On Time [5]	$t_{PO}$		–	300	–	$\mu\text{s}$
Bypass1 Pin Output Voltage [6]	$V_{BYP1}$	$T_A = 25^\circ\text{C}$ , $C_{BYP} = 0.1\text{ }\mu\text{F}$	2.5	2.7	2.9	V
Bypass2 Pin Output Voltage [6] (Elevated SPI Output Mode)	$V_{BYP2}$	$T_A = 25^\circ\text{C}$ , $C_{BYP2} = 0.1\text{ }\mu\text{F}$ ; contact Allegro for availability	2.9	3.1	3.3	V
<b>WAKEx INPUT SPECIFICATIONS</b>						
WAKE Enable High Threshold Voltage	$V_{WAKE(HITH)}$		–	215	–	mV
WAKE Enable Low Threshold Voltage	$V_{WAKE(LOTH)}$		–	115	–	mV
WAKE Input Resistance	$R_{WAKE}$		–	1	–	M $\Omega$
<b>SPI INTERFACE SPECIFICATIONS</b>						
Digital Input High Voltage	$V_{IH}$	MOSIx, SCLKx, $\overline{\text{CSx}}$ pins	2.4	–	5.5	V
Digital Input Low Voltage	$V_{IL}$	MOSIx, SCLKx, $\overline{\text{CSx}}$ pins	–	–	0.5	V
CSx Pin Input Bias Current	$I_{BIAS}$	$V_{CSx} = 3.3\text{ V}$	–	15	–	$\mu\text{A}$
SPI Output High Level	$V_{OH1}$	MISOx pins, $C_L = 20\text{ pF}$ , $C_{BYP1} = 0.1\text{ }\mu\text{F}$ , $C_{BYP2}$ grounded	2.5	2.7	2.9	V
SPI Output High Level (Elevated SPI Output Mode)	$V_{OH2}$	MISOx pins, $C_L = 20\text{ pF}$ , $C_{BYP1} = 0.1\text{ }\mu\text{F}$ , $C_{BYP2} = 0.1\text{ }\mu\text{F}$ . Contact Allegro for availability.	2.9	3.1	3.3	V
SPI Output Low Voltage	$V_{OL}$	MISOx pins, $C_L = 20\text{ pF}$	–	0.3	–	V
SPI Clock Frequency [7]	$f_{SCLK}$	MISOx pins, $C_L = 20\text{ pF}$	0.1	–	10	MHz
SPI Clock Duty Cycle [7]	$D_{ISCLK}$	SPICLK <sub>DC</sub> , 5 V compliant	40	–	60	%
SPI Frame Rate [7]	$t_{SPI}$	5 V compliant	5.8	–	588	kHz
Chip-Select to First SCLK Edge [7]	$t_{CS}$	Time from $\overline{\text{CSx}}$ going low to SCLKx falling edge	50	–	–	ns
Data Output Valid Time [7]	$t_{DAV}$	Data output valid after SCLKx falling edge	–	–	40	ns
MOSI Setup Time [7]	$t_{SU}$	Input setup time before SCLKx rising edge	25	–	–	ns
MOSI Hold Time [7]	$t_{HD}$	Input hold time after SCLKx rising edge	50	–	–	ns
SCLK to CS Hold Time [7]	$t_{CHD}$	Hold SCLKx high time before $\overline{\text{CSx}}$ rising edge	5	–	–	ns
Capacitive Load [8]	$C_L$	Loading on digital output (MISOx) pin with SPI Clock Frequency = 10 MHz	–	–	20	pF

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**OPERATING CHARACTERISTICS (continued):** Valid over the full operating voltage and ambient temperature ranges, unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Unit [2]
<b>PWM INTERFACE SPECIFICATIONS</b> (A1337LLETR-P-DD-T and A1337LLETR-P-T variants only)						
PWM Carrier Frequency	$f_{\text{PWM}}$	PWM Frequency Code = 00	–	122	–	Hz
		PWM Frequency Code = 01	–	1.024	–	kHz
		PWM Frequency Code = 10	–	2.048	–	kHz
PWM Duty Cycle Minimum	$D_{\text{PWM(min)}}$		–	5	–	%
PWM Duty Cycle Maximum	$D_{\text{PWM(max)}}$		–	95	–	%
PWM Output Signal [7]	$V_{\text{PWM(L)}}$	$5\text{ k}\Omega \leq R_{\text{pullup}} \leq 50\text{ k}\Omega$	–	–	0.1	V
	$V_{\text{PWM(H)}}$	Minimum $R_{\text{pullup}} = 5\text{ k}\Omega$	$0.9 \times V_S$	–	–	V
		Maximum $R_{\text{pullup}} = 50\text{ k}\Omega$	$0.7 \times V_S$	–	–	V
Maximum Sink Current	$I_{\text{LIMIT}}$	Output FET on, $T_A = 25^\circ\text{C}$	–	30	–	mA
<b>SENT PROTOCOL SPECIFICATIONS</b> (A1337LLETR-DD-T and A1337LLETR-T variants only)						
SENT Message Duration	$t_{\text{SENT}}$	Tick time = 3 $\mu\text{s}$	–	–	1	ms
Minimum Programmable SENT Message Duration	$t_{\text{SENTMIN}}$	Tick time = 0.5 $\mu\text{s}$ , 3 data nibbles, SCN, and CRC, nibble length = 27 ticks	–	96	–	$\mu\text{s}$
SENT Output Signal	$V_{\text{SENT(L)}}$	$5\text{ k}\Omega \leq R_{\text{pullup}} \leq 50\text{ k}\Omega$	–	–	0.2	V
	$V_{\text{SENT(H)}}$	Minimum $R_{\text{pullup}} = 5\text{ k}\Omega$	$0.9 \times V_S$	–	–	V
		Maximum $R_{\text{pullup}} = 50\text{ k}\Omega$	$0.7 \times V_S$	–	–	V
SENT Output Trigger Signal	$V_{\text{SENTtrig(L)}}$		–	–	1.4	V
	$V_{\text{SENTtrig(H)}}$		2.8	–	–	V
Minimum Time Frame for SENT Trigger Signal	$t_{\text{SENTMIN}}$	Tick time = 0.5 $\mu\text{s}$ , 3 data nibbles, SCN, and CRC, nibble length = 27 ticks	2	–	–	$\mu\text{s}$
Triggered Delay Time	$t_{\text{dSENT}}$	From end of trigger pulse to beginning of SENT message frame. TSENT (SENT_MODE 3 and SENT_MODE 4)	–	7	–	tick
Maximum Sink Current	$I_{\text{LIMIT}}$	Output FET on, $T_A = 25^\circ\text{C}$	–	30	–	mA
<b>DIAGNOSTIC SPECIFICATIONS</b>						
CVH Self-Test Time	$t_{\text{CVHST}}$		–	23	–	ms
Logic BIST Coverage versus Time	$t_{\text{LBISTXX}}$	70% coverage	–	10	–	ms
<b>EEPROM PROGRAMMING PULSES</b>						
Pulse High Time	$t_{\text{PULSE(H)}}$	Time above minimum pulse voltage	8	10	11	ms
Rise Time	$t_r$	10% to 90% of minimum pulse level	300	–	–	$\mu\text{s}$
Fall Time	$t_f$	10% to 90% of minimum pulse level	60	–	–	$\mu\text{s}$
Pulse Voltage	$V_{\text{PULSE}}$	Applied on VCC line	18	19	19.5	V
Separation Time	$t_{\text{PULSE(F-r)}}$	Timing between first pulse dropping below 6 V and 2 <sup>nd</sup> pulse rising above 6 V	0.002	–	50	ms

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**OPERATING CHARACTERISTICS (continued):** Valid over the full operating voltage and ambient temperature ranges, unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Unit [2]	
MAGNETIC CHARACTERISTICS							
Magnetic Field	B	Range of input field	–	–	1500	G <sub>pp</sub>	
TURNS COUNTER CHARACTERISTICS							
Sleep State Period [7]	t <sub>SLEEP</sub>	Default value is 98 ms. Programmable from 2 to 512 ms via EEPROM selection.	2	–	512	ms	
Awake State Period	t <sub>AWAKE</sub>		–	260	–	μs	
Awake State Threshold Acceleration [9]	ε <sub>AWAKE(TH)</sub>	Low-Power Mode	–	–	6000	°/s <sup>2</sup>	
Awake State Threshold Speed [10]	S <sub>AWAKE(TH)</sub>		–	100	–	rpm	
Wake-Up Delay [11][12]	t <sub>dWAKE</sub>	Measured from V <sub>WAKEx</sub> > V <sub>WAKE(HITH)</sub> , V <sub>WAKEx</sub> rising, to beginning of sampling for turns counting	Low RPM mode	–	500	–	μs
			High RPM mode	–	300	–	μs
Counter Range [13]	RANGE	Stored as two's complement	–1280	–	1280	count	

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## OPERATING CHARACTERISTICS (continued): Valid over the full operating voltage and ambient temperature ranges, unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Unit [2]
<b>ANGLE CHARACTERISTICS</b>						
Digital Output Word Length [8]	RES <sub>ANGLE</sub>		–	12	–	bit
Effective Resolution [14]		B = 300 G, T <sub>A</sub> = 25°C, ORATE = 0	–	11.59	–	bit
Angle Refresh Rate [15]	t <sub>ANG</sub>	High RPM mode	–	25	–	μs
		Low RPM mode, AVG = 011 (varies with AVG mode, refer to the appendix <i>Programming Reference</i> )	–	200	–	μs
Response Time	t <sub>RESPONSE</sub>	Low RPM mode (see Figure 4)	–	60	–	μs
Angle Error	ERR <sub>ANG</sub>	T <sub>A</sub> = 25°C, ideal magnet alignment, B = 300 G, target rpm = 0	–	0.5	–	degrees
		T <sub>A</sub> = 150°C, ideal magnet alignment, B = 300 G, target rpm = 0	–1.3	–	1.3	degrees
Angle Noise	N <sub>ANG</sub>	T <sub>A</sub> = 25°C, B = 300 G, 3 sigma noise, no internal filtering	–	0.35	–	degrees
		T <sub>A</sub> = 150°C, no internal filtering, B = 300 G, 3 sigma noise, target rpm = 0	–	0.55	–	degrees
Temperature Drift	ANGLE <sub>DRIFT</sub>	T <sub>A</sub> = 150°C, B = 300 G	–1.4	–	1.4	degrees
		T <sub>A</sub> = –40°C, B = 300 G	–	±1	–	degrees
Angle Drift Over Lifetime	ANGLE <sub>DRIFT-LIFE</sub>	B = 300 G, typical maximum drift observed after AEC-Q100 qualification testing	–	±0.5	–	degrees

[1] Typical data is at T<sub>A</sub> = 25°C and V<sub>CC</sub> = 5 V, and it is for design estimates only.

[2] 1 G (gauss) = 0.1 mT (millitesla).

[3] At power-on, a die will not respond to commands until V<sub>CC</sub> rises above V<sub>UVLOHI</sub>. After that, the die will perform and respond normally until V<sub>CC</sub> drops below V<sub>UVLOLOW</sub>.

[4] VCC Low Threshold Flag will be sent via the SPI interface as part of angle measurement.

[5] During the power-on time period, the A1337 SPI transactions are not guaranteed.

[6] The output voltage and current specifications are to aid in PCB design. The is not intended to drive any external circuitry. The specifications indicate peak capacitor charging and discharging currents to be expected during non-operation.

[7] Parameter is not guaranteed at final test. Determined by design.

[8] RES<sub>ANGLE</sub> represents the number of bits of data available for reading from die registers.

[9] Acceleration greater than ε<sub>AWAKE(TH)</sub> while in Low Power mode may result missed 180° crossings. To capture greater rates of acceleration, the WAKE should be asserted.

[10] When the die logic determines the velocity of the magnet is greater than S<sub>AWAKE(TH)</sub>, the die will stay in the Awake state.

[11] Measured from V<sub>WAKE</sub> > V<sub>WAKE(HITH)</sub>, V<sub>WAKE</sub> rising, to beginning of sampling for turns counting. There are three alternative conditions for waking up: V<sub>WAKE</sub> > V<sub>WAKE(HITH)</sub>, V<sub>IH</sub>, host removes Sleep condition by means of the SPI lines, or S<sub>AWAKE</sub> > 100 rpm.

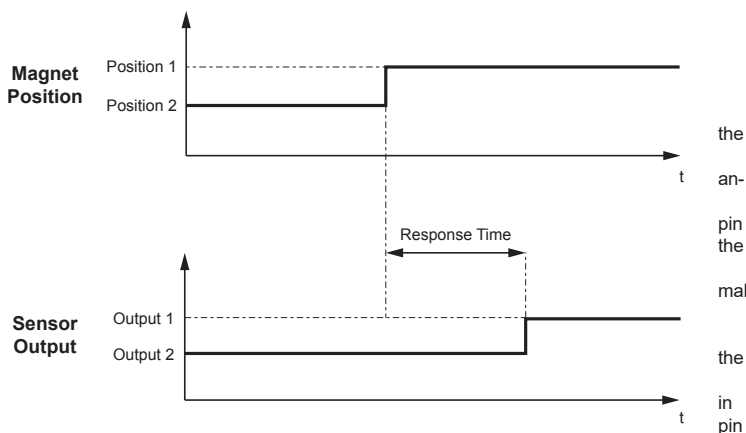
[12] To calculate Low RPM mode, time = 300 μs + 25 × 2<sup>AVG</sup>. Given AVG = 011 = 3 (decimal), so 2<sup>3</sup> = 8.

[13] Turns Counter step size can be selected between 45 degrees, and 180 degrees, by setting an EEPROM bit.

[14] Effective Resolution is calculated using the formula below:

$$\log_2(360) - \log_2\left(\frac{1}{n} \sum_{i=1}^n \sigma_i\right)$$

[15] The rate at which a new angle reading will be ready.



**Definition of Response Time**

## FUNCTIONAL DESCRIPTION

### Overview

The A1337 is a rotary position Hall-sensor-based device. It incorporates up to two electrically independent Hall-based sensor dies in the same surface-mount package to provide solid-state consistency and reliability, and to support a wide variety of automotive applications. Each Hall-sensor-based die measures the direction of the magnetic field vector through 360° in the x-y plane (parallel to the branded face of the device) and computes an angle measurement based on the actual physical reading, as well as any internal configuration parameters that have been set by the user. The output of each die is used by the host microcontroller to provide a single channel of target data.

This device is an advanced, programmable system-on-chip (SoC). Each integrated circuit includes a Circular Vertical Hall (CVH) analog frontend, a high-speed sampling A-to-D converter, digital filtering, digital signal processing, and an SPI, SENT, or PWM output of the processed angle data.

### Angle Measurement

The A1337 can monitor the angular position of a rotating magnet at speeds ranging from 0 to more than 7600 rpm. At lower rotational speeds, the A1337 is able to measure angle data with minimal angular latency between the actual magnet and sensor output. As the RPM increases, the angular latency between the magnet and sensor output also increases. Above 7600 rpm, the A1337 continues to provide angle data, however the accuracy is proportionally reduced.

The A1337 can be configured to operate in two angular measurement modes of operation: Low RPM mode, and High RPM mode. Low RPM mode allows a programmable number of internal angle samples to be accumulated and averaged, providing greater resolution while reducing the update rate. This is suitable for lower rpm applications (0 to ≈500 rpm). For high speed applications, the averaging function may be bypassed by operating in High RPM mode.

The actual update rate of Low RPM mode can be changed by setting the AVERAGING bits in the EEPROM (see the appendix *Programming Reference* for details). Table 1 describes the different levels of averaging available in Low RPM mode. A setting of 000<sub>2</sub> is equivalent to High RPM mode.

Table 1: Refresh Rate Based on Quantity of Samples Averaged

"AVG [2:0]"	Quantity of Samples Averaged	"Refresh Rate (μs)"
000	1	25
001	2	50
010	4	100
011	8	200
100	16	400
101	32	800
110	64	1600
111	128	3200

The A1337 has a typical output bandwidth of 40 kHz (25 μs refresh rate) in High RPM mode. In High RPM mode, a new angle measurement is available at the internal angle output register to be transmitted over the SPI/SENT or PWM output ports every 25 μs. There is a latency of 60 μs from when there is a change in the position of the target magnet field to when the new representative angle is updated in the internal angle output register. This latency effectively represents the age of the angle measurement.

### Impact of High Speed Sensing

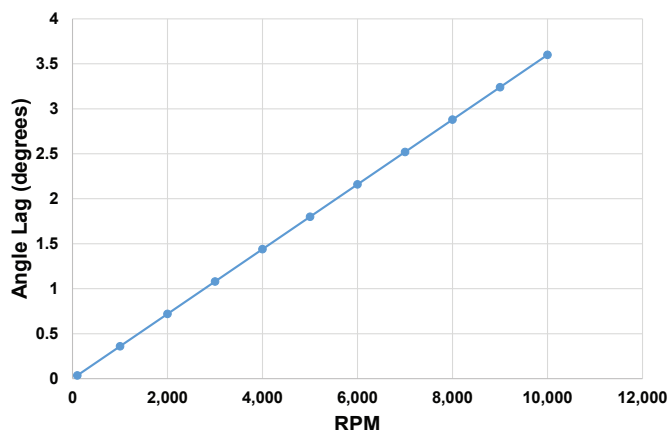
Due to signal path latency, the angle information is delayed by  $t_{\text{RESPONSE}}$ . This delay equates to a greater angle value as the rotational velocity increases (i.e. a magnet rotating at 20,000 rpm traverses twice as much angular distance in a fixed time period as a magnet rotating at 10,000 rpm), and is referred to as angular lag.

The lag is directly proportional to RPM, and may be compensated for externally, if the velocity is known.

Angular lag can be expressed using the following equation:

$$\text{Angle\_Lag} = (\text{rpm} \times 6) / (16 \times t_{\text{RESPONSE}}) \quad (1)$$

where rpm represents the rotational velocity of the magnet, Angle\_lag is expressed in degrees, and  $t_{\text{RESPONSE}}$  is in μs.



**Figure 1: Angle Lag versus RPM, 60  $\mu$ s Response Time**

In addition to using the internal averaging of the sensor, angle resolution is also dependent on the intensity (B, in gauss) of the applied magnetic field from the target. At lower intensities, a reduced signal-to-noise ratio will cause one or two LSBs to change state randomly due to noise. These factors work together, so when High RPM mode is selected, the effective range of resolution is 8 to 10 bits (from lower to higher field intensities), and in Low RPM mode, the effective range is 11 to 12 bits, depending on field strength and AVG selection.

Regardless of the field intensity and mode selection, the transmission protocol and number formatting remains the same. The MSB is always transmitted first. The entire number should be read.

The Output Angle is always calculated at maximum resolution. To be more explicit:

$$Angle_{OUT} = 360 (^{\circ}) \times D[12:0] / (2^{13}) \quad (2)$$

This formula is always true, regardless of the applied field intensity. What changes with the field and speed setting is how “quiet” the LSBs of the measurement data (D 12:x) will be.

It should be noted that the secondary die (E2) is rotated 180° relative to the primary die (E1). This results in a difference in measurement of approximately 180° between the two die, given perfect alignment of each die to the target magnet.

This phenomenon can be counteracted by subtracting the offset using a microprocessor. Alternatively, the difference between the two die can be compensated for using the EEPROM for setting the Reference Angle.

## Programming Modes

The EEPROM can be programmed through the dedicated SPI interface pins or via Manchester encoding on the VCC pin, allowing process coefficients to be entered and options selected. (Note: programming EEPROM also requires the VCC line to be pulsed, which could adversely effect other devices if powered from the same line). The EEPROM provides persistent storage at end of line for final parameters.

## SPI System-Level Timing

The A1337 outputs a new angle measurement every  $t_{ANG}$   $\mu$ s. In High RPM mode, the A1337 outputs a new angle measurement every  $t_{ANG}$   $\mu$ s, with an effective resolution of 10 bits. There is, however, a latency of  $t_{LAT}$ , from when the rotating magnet is sampled by the CVH to when the sampled data has been completely transmitted over the SPI interface. Because an SPI interface Read command is not synchronous with the CVH timing, but instead is polled by the external host microcontroller, the latency can vary. For single back-to-back SPI transactions (first transaction is sending the Read register 0x0 command, second is retrieving the angle data) the following scenarios are possible:

- Worst case: 2 CVH cycle + 2 SPI cycles
- Best case: 1.5 SPI cycles; 2  $\mu$ s, assuming a 10 MHz SPI clock

## Power-Up

Upon applying power to the A1337, the device automatically runs through an initialization routine. The purpose of this initialization is to ensure that the device comes up in the same predictable operating condition every power cycle. This initialization routine takes a finite amount of time to complete, which is referred to as Power-On Time,  $t_{PO}$ .

The A1337 wakes up in a default state that sets all SPI registers to their default value. It is important to note that, regardless of the state of the device before a power cycle, the device will re-power with default values. For example, on every power-up, the device will power up in the mode set in the EEPROM bit RPM. The state of the EEPROM is unchanged.

## Normal Power Mode

In Normal Power Mode, the IC draws maximum current (nominally 8.25 mA—see Normal Mode Supply Current specification in the A1337 datasheet for more details) to operate its full feature set, and updates the angle output register at the fastest rate as selected by RPM mode and AVG settings (see the A1337 programming reference for more details).

## Low Power Mode

Low Power Mode is useful for battery-powered applications where the task of tracking the target's rotation can be delineated into one of two mission modes. The first mission mode would be similar to an angle tracking mode, where the sensor tracks the output at full bandwidth and provides its measure of the angular output at full resolution. The second mission mode can be considered as a turns-tracking mode. In this mode, the sensor does not need to track the angle at full resolution—it is sufficient to track the Turns Count value of the target. The size of one turns-count unit can be preselected via EEPROM setting in the A1337 to be either 180 or 45 degrees. The A1337 tracks  $\pm 1280$  turns in both directions. In Low Power Mode, the A1337 is mostly held in a lower quiescent current consumption state. The IC does not provide normal angle readings over the SPI, SENT, or PWM interfaces, but wakes up periodically to check for the occurrence of Turns Counts. The off-time of the Low Power Mode operation can be adjusted by the user based on the application, by programming on-chip EEPROM memory. Figure 2 shows Average  $I_{CC}$  in  $\mu A$  versus the programmable off-time  $t_{OFF}$ .

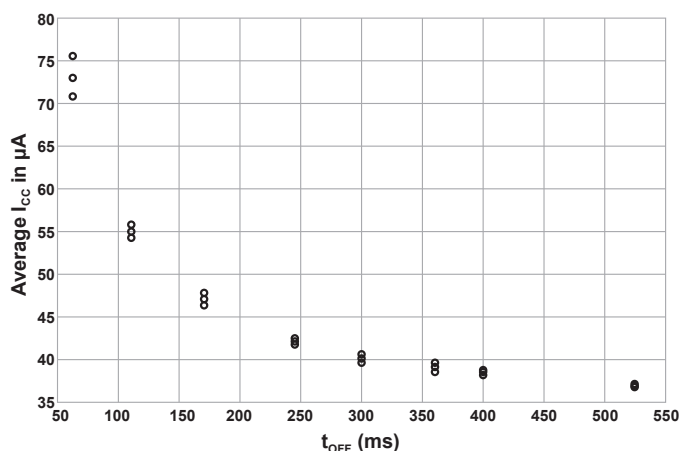


Figure 2: A1337 Average  $I_{CC}$  vs.  $t_{OFF}$ , measured at 150°C

## Transport Mode

Certain battery-powered applications require especially low power consumption from the IC during long-term storage and/or transportation (for example, when a new car is being transported from the assembly line to the dealer). To meet this need, the A1337 features an ultra-low power mode called Transport Mode. Transport Mode is used to put the A1337 into a deep-sleep state for ultra-low power consumption. When in this mode, the sensor IC does not track angle or turns counts. Typically, the IC consumes 30  $\mu A$  of current per die when in Transport Mode.

## WAKE Pin

The A1337 also offers a WAKE input pin. This pin is intended to wake up the device from Low Power Mode, in special cases where the motor acceleration is too high, and the system cannot afford to wait for the entire Low Power Sleep time to expire, before the next periodic wakeup. When the voltage threshold on the WAKE pin exceeds  $V_{WAKE(HITH)}$ , the IC will wake up from Low Power Mode and begin to track Turns as it would in normal power mode. This pin is usually connected to a filtered version of the back-EMF voltage signal from the motor being used. This allows fast feedback from the motor to the Turns-Count circuit, in the case of high acceleration events.

## Transitioning Between Modes

The A1337 is designed so that it can transition between Normal Power Mode (NPM), Low Power Mode (LPM), and Transport Mode (TPM) based on either a command from the system microcontroller, by magnetic target rotation, or by exceeding the WAKE pin threshold,  $V_{WAKE(HITH)}$ . This dual scheme ensures that valuable TC information is not lost due to the target rotating too quickly while the sensor is in Low Power Mode.

To better understand this, consider a few scenarios based on the state diagram shown in Figure 3, as well as the information shown in Table 2. Assume that the sensor is powered up and in NPM. It would therefore be able to provide all the functionality as described under NPM in Table 2. Now, if the controller decided that to save power it should enter LPM, then it would have to satisfy all the conditions outlined in branch A of Figure

3 in order to enter LPM. In other words, the A1337 SPI lines would have to be held low for  $>50\ \mu s$ , the WAKE pin voltage on the A1337 IC would have to be lower than the threshold  $V_{WAKE(LOTH)}$ , and the target rpm of the magnet would have to be lower than an average speed  $S_{AWAKE(TH)}$ . If all these conditions were met, then the IC would transition into LPM. While in LPM, the IC would be able to support the TC tracking functionality as described in Table 2.

If the system now needed to wake up from LPM and re-enter NPM, it would need to then satisfy any one of the conditions outlined in branch B of Figure 3—in other words, initiating activity on SPI pins, or rotating the target faster than  $S_{AWAKE(TH)}$ , or applying a voltage higher than  $V_{WAKE(LOTH)}$  on the WAKE pin.

In a similar manner, the system can navigate between NPM, LPM, and TM, by meeting the appropriate conditions as specified by branches A, B, C or D of the state diagram.

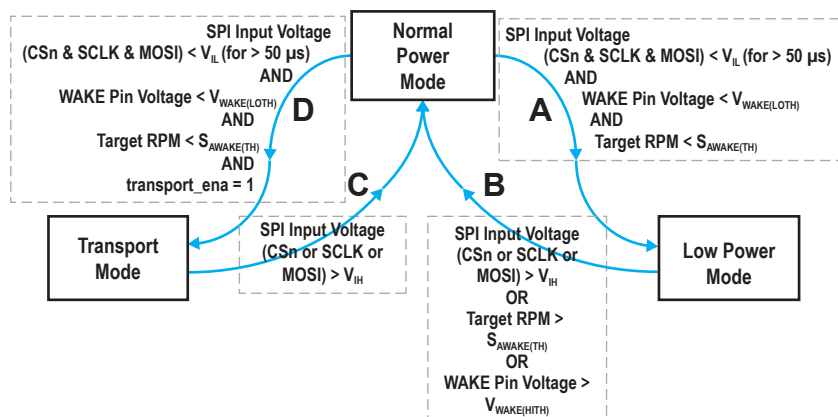


Figure 3: Operating Mode State Diagram

Table 2: Mode States

	Normal Power Mode (NPM)	Low Power Mode (LPM)	Transport Mode (TPM)
Angle Sensor Functionality	Available Communication Protocols: <ul style="list-style-type: none"> <li>SPI 4-wire</li> <li>PWM</li> <li>SENT</li> <li>Manchester Code</li> </ul>	Available Communication Protocols: <ul style="list-style-type: none"> <li>Not Applicable</li> </ul>	Available Communication Protocols: <ul style="list-style-type: none"> <li>Not Applicable</li> </ul>
	Available Angle Output Data: <ul style="list-style-type: none"> <li>12-bit absolute angle value</li> <li>Turns-Count (TC)</li> </ul>	Available Angle Output Data: <ul style="list-style-type: none"> <li>Turns-Count (TC)*</li> </ul> <p>*TC values are tracked in LPM, but available for read-only upon exiting LPM.</p>	Available Angle Output Data: <ul style="list-style-type: none"> <li>Not Applicable</li> </ul>
Current Consumption	8.5 mA nominal per die	55 $\mu A$ nominal per die <b>100× power savings</b>	30 $\mu A$ nominal per die <b>280× power savings</b>



## User-Programmable Features for Low Power Mode and Turns Counting

The A1337 allows programmability of its LPM function. For instance, the IC provides the ability to select the size of its Turns-Count. Two choices are available: 180° or 45°. This feature is selectable via the TC1 bit in EEPROM address 0x15, Bit 18. In a similar manner, other functions of the LPM operation can also be programmed in EEPROM. Table 3 summarizes these features, with default values.

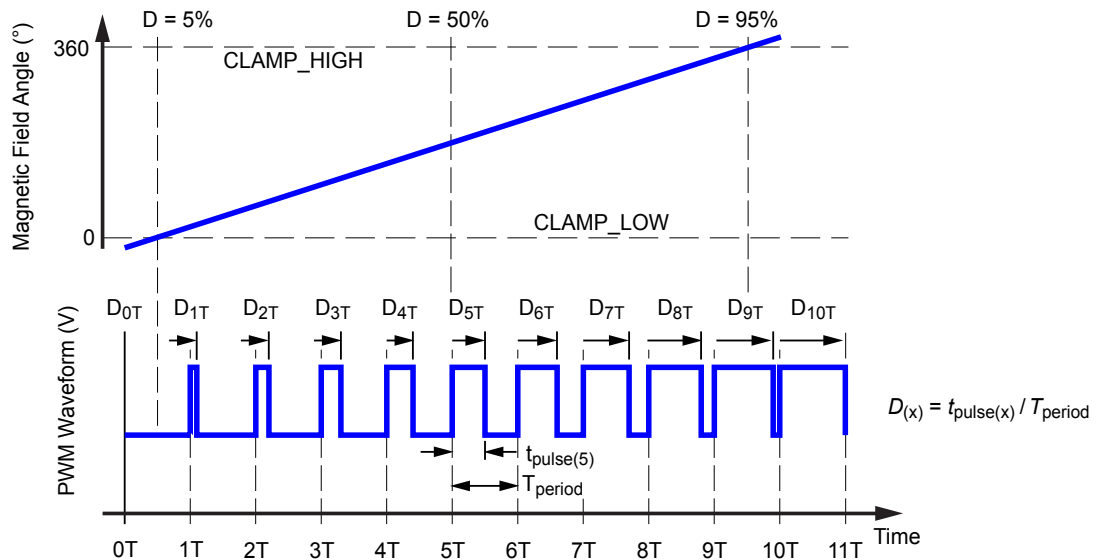
**Table 3: User-Programmable Features**

Field	EEPROM Address	Size (bits)	Default <sup>[1]</sup> (Binary, Decimal)	Value	Function
TC1	0x15, Bit18	1	(0) <sub>2</sub>	0	180 Degree Turns-Count
				1	45 Degree Turns-Count
LOW_POWER_OFF_TIMER	0x15, (Bit17:10)	8	(00110000) <sub>2</sub> , (48) <sub>10</sub>	—	Sets LPM Off-time from ~2 ms to ~500 ms. In 2 ms steps.
NORMAL_POWER_SPEED_TIMER	0x15, (Bit9:0)	9	(0010011101) <sub>2</sub> , (157) <sub>10</sub>	—	Sets the time interval over which the angular velocity of the target is measured. To ensure proper operation to datasheet specs, it is recommended to set this parameter to its default value.
NORMAL_POWER_ANGLE_THRESHOLD	0x16, (Bit22:12)	11	(00000011010) <sub>2</sub> , (26) <sub>10</sub>	—	Sets the maximum allowable angle displacement over the time set by NP_SPEED_TIMER. To ensure proper operation to datasheet specs, it is recommended to set this parameter to its default value.
LOW_POWER_ANGLE_THRESHOLD	0x16, (Bit10:0)	11	(01010101010) <sub>2</sub> , (682) <sub>10</sub>	—	Sets the maximum allowable angle displacement over the time set by LP_OFF_TIMER. To ensure proper operation to datasheet specs, it is recommended to set this parameter to its default value.

<sup>[1]</sup> Default values for LP\_OFF\_TIMER, NP\_SPEED\_TIMER, NP\_ANGLE\_THRESHOLD, and LP\_ANGLE\_THRESHOLD are for Angular Motion with Constant Acceleration (max acceleration 6000°/s<sup>2</sup>) and t<sub>OFF</sub> = 98 ms.

## PWM Output (“-P-” option)

The A1337LLETR-P-DD-T and A1337LLETR-P-T options provide a pulse-width-modulated output with duty cycle being proportional to the measured angle. The PWM duty cycle ranges between 5% (corresponding to 0° angle) and 95% (corresponding to 360° angle). The 0% and 100% (Pulled Low, and Pulled High) states are reserved for error condition notifications.



**Figure 4: PWM mode outputs a duty-cycle-based waveform that can be read by the external controller as a cumulatively changing continuous voltage.**



## MANCHESTER SERIAL INTERFACE

To facilitate addressable device programming when using the unidirectional SENT output mode with no need for additional wiring, the A1337 incorporates a serial interface on the VCC line. (Note: The A1337 may be programmed via the SPI interface, with additional wiring connections. For detailed information on part programming, refer to the A1337 programming manual). This interface allows an external controller to read and write registers in the A1337 EEPROM and volatile memory. The device uses a point-to-point communication protocol, based on Manchester encoding per G.E. Thomas (a rising edge indicates a 0 and a falling edge indicates a 1), with address and data transmitted MSB first. The addressable Manchester code implementation uses the logic states of the SA0 (SPI  $\overline{CS}$  Pin) / SA1 (SPI SCLK Pin) to set address values for each die. In this way, individual communication with up to four A1337 die is possible.

To prevent any undesired programming of the A1337, the serial interface can be disabled by setting the Disable Manchester bit (0x19 bit 18) to a 1. With this bit set, the A1337 will ignore any Manchester input on VCC.

### Entering Manchester Communication Mode

Provided the Disable Manchester bit is not set in EEPROM, the A1337 continuously monitors the VCC line for valid Manchester commands. The part takes no action until a valid Manchester Access Code is received.

There are two special Manchester code commands used to activate or deactivate the serial interface and specify the output format used during Read operations:

1. **Manchester Access Code:** Enters Manchester Communication Mode; Manchester code output on the SENT pin.
2. **Manchester Exit Code;** returns the SENT pin to normal (angle data) output format.

Once the Manchester Communication Mode is entered, the SENT output pin will cease providing angle data, interrupting any data transmission in progress.

### Transaction Types

As shown in Figure 5, the A1337 receives all commands via the VCC pin, and responds to Read commands via the SENT pin. This implementation of Manchester encoding requires the communication pulses be within a high ( $V_{MAN(H)}$ ) and low ( $V_{MAN(L)}$ ) range of voltages on the VCC line. Writing to EEPROM is supported by two high voltage pulses on the VCC line.

Each transaction is initiated by a command from the controller; the A1337 does not initiate any transactions. Two commands are recognized by the A1337: Write and Read.

### Writing to EEPROM

When a Write command requires writing to non-volatile EEPROM, after the Write command, the controller must also send two *Programming pulses*, high-voltage strobes via the VCC pin. These strobes are detected internally, allowing the A1337 to boost the voltage on the EEPROM gates. Refer to the programming manual for specifics on sensor programming and protocol details.

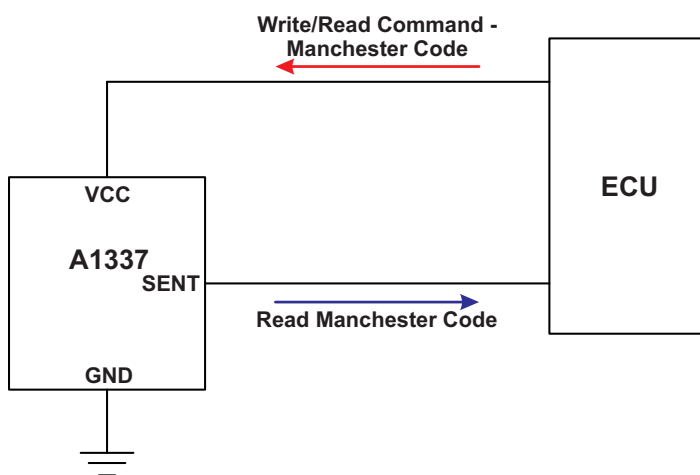


Figure 5: Top-Level Programming Interface

## Manchester Interface Reference

Table 4: Manchester Interface Protocol Characteristics [1]

Characteristics	Symbol	Note	Min.	Typ.	Max.	Unit
<b>INPUT/OUTPUT SIGNAL TIMING</b>						
Bit Rate		Defined by the input message bit rate sent from the external controller	4	–	50	kbps
Bit Time	$t_{\text{BIT}}$	Data bit pulse width at 4 kbps	243	250	257	$\mu\text{s}$
		Data bit pulse width at 100 kbps	9.5	10	10.5	$\mu\text{s}$
Bit Time Error	$\text{err}_{\text{TBIT}}$	Deviation in $t_{\text{BIT}}$ during one command frame	–11	–	+11	%
Write Delay	$t_{\text{WRITE(E)}}$	Required delay from the end of the second EEPROM Program pulse to the leading edge of a following command frame	$V_{\text{CC}} < 6.0 \text{ V}$	–	–	–
Read Delay	$t_{\text{START\_READ}}$	Delay from the trailing edge of a Read command frame to the leading edge of the Read Acknowledge frame	$\frac{1}{4} \times t_{\text{bit}}$	–	$\frac{3}{4} \times t_{\text{bit}}$	$\mu\text{s}$
<b>EEPROM PROGRAMMING PULSE</b>						
EEPROM Programming Pulse Setup Time	$t_{\text{sPULSE(E)}}$	Delay from last bit cell of write command to start of EEPROM programming pulse	40	–	–	$\mu\text{s}$
Pulse High Time	$t_{\text{PULSE(H)}}$	Time above minimum pulse voltage	8	10	11	ms
Rise Time	$t_r$	10% to 90% of minimum pulse level	300	–	–	$\mu\text{s}$
Fall Time	$t_f$	10% to 90% of minimum pulse level	60	–	–	$\mu\text{s}$
Pulse Voltage	$V_{\text{PULSE}}$	Applied on VCC Line	18	19	19.5	V
Separation Time	$t_{\text{PULSE(f-r)}}$	Timing between first pulse dropping below 6 V and 2nd pulse rising above 6 V	0.002	–	50	ms
<b>INPUT SIGNAL VOLTAGE</b>						
Manchester Code High Voltage	$V_{\text{MAN(H)}}$	Applied to VCC line	7.8	–	–	V
Manchester Code Low Voltage	$V_{\text{MAN(L)}}$	Applied to VCC line	–	–	6.3	V
<b>OUTPUT SIGNAL VOLTAGE (Applied on SENT Line)</b>						
Manchester Code High Voltage	$V_{\text{MAN(H)}}$	Minimum $R_{\text{pullup}} = 5 \text{ k}\Omega$	$0.9 \times V_{\text{S}}$	–	–	V
		Maximum $R_{\text{pullup}} = 50 \text{ k}\Omega$	$0.7 \times V_{\text{S}}$	–	–	V
Manchester Code Low Voltage	$V_{\text{MAN(L)}}$	$5 \text{ k}\Omega \leq R_{\text{pullup}} \leq 50 \text{ k}\Omega$	–	–	0.2	V

[1] Determined by design.

## SENT Output Mode

(A1337LLETR-DD-T, A1337LLETR-T options)

The SENT output converts the measured magnetic field angle to a binary value mapped to the Full-Scale Output (FSO) range of 0 to 4095, shown in Figure 6. This data is inserted into a binary pulse message, referred to as a frame, that conforms to the SENT data transmission specification (SAEJ2716 JAN2010).

The SENT frame may be configured via EEPROM. The A1337 may operate in one of three broadly defined SENT modes (see the A1337/8 Programming Manual for details on SENT modes and settings).

- SAE J2716 SENT: free-streaming SENT frame in accordance with industry specification.
- Triggered SENT (TSENT): User-defined sampling and retrieval.
- Shared SENT: Allows multiple devices to share a common SENT line. Devices may either be directly addressed (Addressable SENT or ASSENT) or sequentially polled (Sequential SENT or SSSENT).

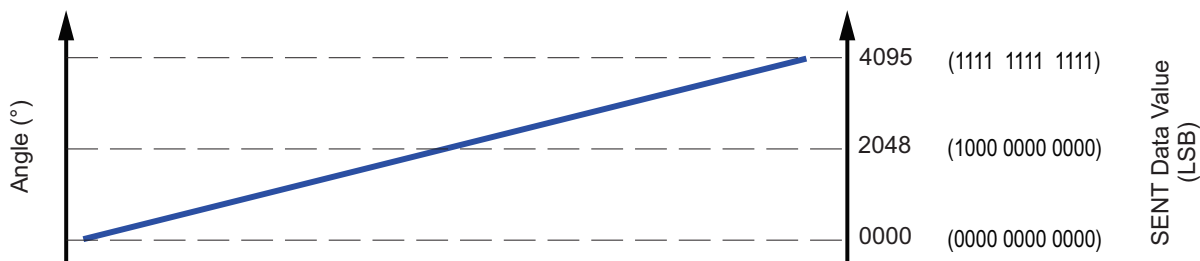


Figure 6: Angle is represented as a 12-bit digital value.

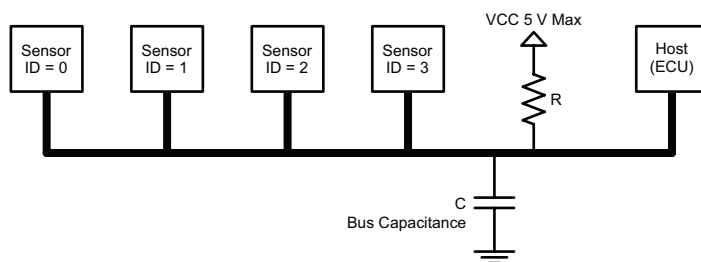


Figure 7: Allegro's proprietary SENT protocol allows multiple parts to share one common output bus.

SENT MESSAGE STRUCTURE

Data within a SENT message frame is represented as a series of nibbles, with the following characteristics:

- Each nibble is an ordered pair of a low-voltage interval followed by a high-voltage interval
- The low-voltage interval acts as the delimiting state which acts as a boundary between each nibble. The length of this low-voltage interval is fixed at 5 ticks.
- The high-voltage interval performs the job of the information state and is variable in duration in order to contain the data payload of the nibble
- The slew rate of the falling edge may be adjusted using the C\_SENT\_DRIVE parameter.

The duration of a nibble is denominated in ticks. The period of a tick is set by the C\_TICK\_TIME parameter. The duration of the nibble is the sum of the low-voltage interval plus the high-voltage interval.

The parts of a SENT message are arranged in the following required sequence (see Figure 9):

1. **Synchronization and Calibration:** Flags the start of the SENT message.
2. **Status and Communication Nibble:** Provides A1337 status and the optional serial data determined by the setting of the SENT\_SERIAL parameter.
3. **Data:** Angle information and optional data.
4. **CRC:** Error checking.
5. **Pause Pulse (optional):** Fill pulse between SENT message frames.

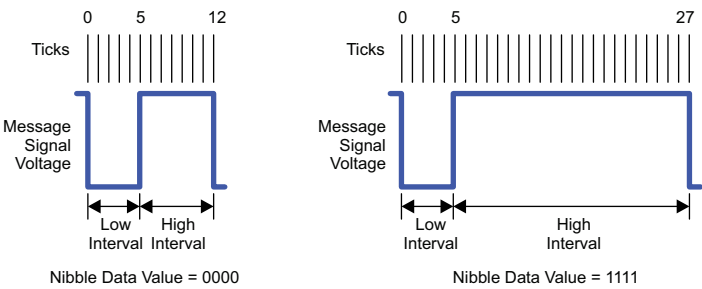


Figure 8: General Value Formation for SENT  
0000 (left), 1111 (right)

Table 5: Nibble Composition and Value

Quantity of Ticks			Binary (4-bit) Value	Decimal Equivalent Value
Low-Voltage Interval	High-Voltage Interval	Total		
5	7	12	0000	0
5	8	13	0001	1
5	9	14	0002	2
⋮	⋮	⋮	⋮	⋮
5	21	26	1110	14
5	22	27	1111	15

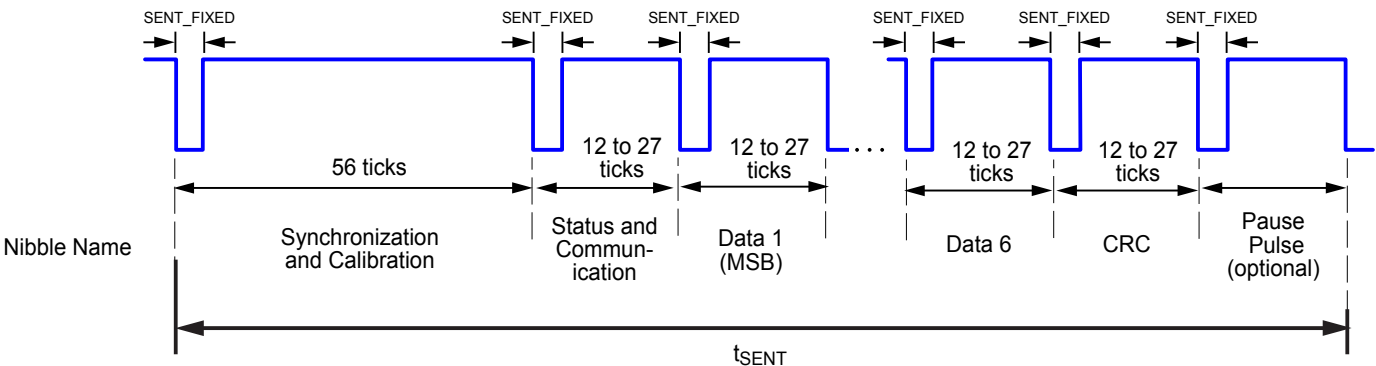


Figure 9: General Format for SENT Message Frame

Table 6: EEPROM Registers Map Table with Defaults (Factory Reserved Registers Not Shown) [1]

EADR	State	Bits																								
		23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
0x11	CUST1	RES																				RES				
		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	
0x15	LP_CFG1	RES				TC1		LOW_POWER_OFF_TIMER							NORMAL_POWER_SPEED_TIMER											
		0	0	0	0	0	0	0	0	1	1	0	0	0	0	0	0	1	0	0	1	1	1	0	1	
0x16	LP_CFG2	RES	NORMAL_POWER_ANGLE_THRESHOLD										RES	LOW_POWER_ANGLE_THRESHOLD												
		0	0	0	0	0	0	0	1	1	0	1	0	0	0	1	0	1	0	1	0	1	0	1	0	
0x17	SENT_CFG	ZS	SS	SM	PO	IS	RES	SCN_MODE			DATA_MODE			SENT_MODE			TICK_TIME					SENT_DRIVE				
		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0		
0x18	CUST_CFG1		CIS			DA	MAXID		NS	FA				MISSING_MAG_THRESHOLD												
		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	1	1	0	
0x19	CUST_CFG2	LOCK	RES	PWM_F		RES	MAND	SCRC	RPMD	AVERAGE			POL	ANGLE_OFFSET												
		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	
0x1E	ERM	ES										MAN2	MAN	UV	LBST	CVHST	GOVF	AH	AL	EU	ES	TR	TRNO	IE	MAGM	BATD
		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	
0x1F	CUST2	CUST_EEP																								
		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	

[1] For more details, see Programming Manual.

## Diagnostics

The A1337 was designed with ISO 26262 requirements in mind and supports a number of on-chip self diagnostics to enable the host microcontroller to assess the operational status of each die. For example each die can be user configured for logic built-in self-test (L-BIST) evaluation to ensure the digital circuits are operational. Upon completion of an L-BIST operation the A1337 will set a pass/fail L-BIST status flag in the device error (ERR) register.

Each A1337 die also supports several diagnostic features and status flags, accessible via a SPI read of the ERR register, to let the user know if any issues are present with the A1337 or associated magnetic system, as shown in Table 7.

In addition, each die on the A1337 supports an on-chip user initiated diagnostic (CVH Self-Test) mode that tests the entire signal path, including the front end Circular Vertical Hall sensing circuitry.

## USER-INITIATED DIAGNOSTICS

Each die on the A1337 can independently be controlled by a microcontroller to enter its CVH Self-Test mode via SPI or SENT.

When a CVH Self-Test mode operation is requested by the microcontroller the respective die initiates a test mode sequence whereby it sequentially applies an internal constant bias current to every contact element in the Circular Vertical Hall ring. As each element in the Circular Vertical Hall ring is sequentially biased, an angle measurement is calculated.

The time to complete one revolution around the Circular Vertical Hall ring and calculate and store incremental angle measurements is  $t_{CVHST}$ .

**Table 7: Diagnostic Capabilities**

Diagnostic/ Protection	Description	Output State
Loss of $V_{CC}$	Determine if battery power was lost	BATD Error flag is set; see ERR register table.
Reverse $V_{CC}$ Condition	Current Limiting ( $V_{CCx}$ pin)	Output Below GND.
MISO/SENT/PWM Short to VCC	Current Limiting (MISOx pin)	MISO/SENT/PWM Line: Pulled up to V-pullup. Should not be tied to VCC if $V_{CC} > 5.5$ V.
MISO/SENT/PWM Short to Ground	Current Limiting (MISOx pin)	MISO/SENT/PWM Line: Pulled up to GND.
Logic Built-In Self-Test (LBIST)	70% coverage for 10 ms BIST of all digital circuitry	Error Flags set in SPI message when errors are detected; see ERR2 Register table.
Signal Path Diagnostics	User controlled advanced CVH and full signal path diagnostics	Error Flags set in SPI message when errors are detected; see ERR2 Register table.
Internal Error	Monitors digital logic for proper function	IERR Error flag is set; see ERR Register table.
Missing Magnet	Monitors magnet field level in case of mechanical failure	MAGM Error flag is set; see ERR Register table.
EEPROM Error Detection and Correction	Detection of single and dual bit error, and correction of single bit error.	Error flags set in SPI message when errors are detected or corrected; see ERR Register table.
$V_{CC}$ Low Flag	Asserted when $V_{CC} < V_{UVLOTH}$	Bit 2 of SPI Output on MISO is set high. See Programming manual for more details.
Temperature Out of Range	Die temperature has exceeded acceptable range	See ERR Register table for more details
Redundancy	Dual-die version of the A1337 provides redundant sensors in the same package	

Table 8: Primary Serial Interface Registers Bits Map (Reserved Registers Not Shown)

Serial Address	Register Symbol	Addressed Byte (MSB)												
		12	11	10	9	8	7	6	5	4	3	2	1	0
0x04	ERR	–	–	–	–	–	–	EEP2	EEP1	TMP	TRNO	IERR	MAGM	BATD
0x05	ERR2	–	–	–	–	–	–	MANER	RES3	LBIST	CVHST	RES2	RES1	RES0
0x08	CTRL	–	–	–	–	–	–	–	–	STS	TRST	RPM	PWR	ERST

## ERR (Error) Register Address: 0x04

Address	0x04												
Bit	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	–	–	–	–	–	–	EEP2	EEP1	TMP	TRNO	IERR	MAGM	BATD
R/W	–	–	–	–	–	–	R	R	R	R	R	R	R
Value	X	X	X	X	X	X	0/1	0/1	0/1	0/1	0/1	0/1	0/1
Reset	0	0	0	0	0	0	0	0	0	0	0	0	1

Error register. Indicates various current error conditions. When set, can only be cleared via the CTRL register ERST field, hard reset, or power-on reset (see BATD for exception). If any of the error bits are asserted, the error flag on the serial interface will be asserted. Masking an error bit will prevent the bit from asserting the serial interface error flag, but the error bit may still be asserted in this register.

### EEP2 [6] EEPROM Error Flag 2

Uncorrectable dual-bit EEPROM error flag.

Bit	Value	Description
6	0	Error condition not present
	1	Error condition present

### EEP1 [5] EEPROM Error Flag 1

Corrected single-bit EEPROM error flag.

Bit	Value	Description
5	0	Error condition not present
	1	Error condition present

### TMP [4] Temperature Out of Range

This bit indicates an error condition when the die temperature has exceeded the acceptable range.

Bit	Value	Description
4	0	Error condition not present
	1	Error condition present

### TRNO [3] Turns Count Data Overflow (A1337 only)

Indicates an overflow in the turns count output data.

Bit	Value	Description
3	0	Error condition not present
	1	Error condition present

### IERR [2] Internal Error

This bit is set to 1 if an internal logic error condition has been detected. When this bit is set to 1, a general reset is recommended.

Bit	Value	Description
2	0	No digital logic timer error has been detected.
	1	Digital logic timer error has been detected.

### MAGM [1] Target Magnet Loss

Monitors target magnet field level to detect field loss due to mechanical failure in the application.

Bit	Value	Description
1	0	Error condition not present
	1	Error condition present

### BATD [0] Low Power Mode Supply Loss

Indicates if battery power (VCC supply) was lost during Low Power mode. By default also indicates at expected low power events: start-up, power-on reset, and after exiting Transport mode. Before commencing normal operation, must be set to 0 by asserting the ERST bit of the CTRL register (unless field is masked in EEPROM by ERM register BATD field).

Bit	Value	Description
0	0	Error condition not present
	1	Error condition present

**ERR2 (Error2) Register**

Address: 0x05

Address	0x05												
Bit	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	–	–	–	–	–	–	MANER	RES3	LBIST	CVHST	RES2	RES1	RES0
R/W	–	–	–	–	–	–	R	–	R	R	–	R	R
Value	X	X	X	X	X	X	0/1	–	0/1	0/1	–	0/1	0/1
Reset	0	0	0	0	0	0	0	–	0	0	–	0	1

Error register. Indicates various current error conditions. When set, can only be cleared via the CTRL register ERST field, hard reset, or power-on reset (see BATD for exception). If any of the error bits are asserted, the error flag on the serial interface will be asserted. Masking an error bit will prevent the bit from asserting the serial interface error flag, but the error bit may still be asserted in this register.

**MANER [6] Manchester/SENT Error Flag**

Indicates Manchester/SENT Error.

Bit	Value	Description
6	0	Error condition not present
	1	Error condition present

**RES2 [2] Factory Reserved Bit****RES1 [1] Factory Reserved Bit****RES0 [0] Factory Reserved Bit****RES3 [5] Factory Reserved Bit****LBIST [4] LBIST Error Flag**

This bit indicates that the Logic Built-In Self-Test (LBIST) failed.

Bit	Value	Description
4	0	Error condition not present
	1	Error condition present

**CVHST [3] Circular Vertical Hall Self-Test**

This bit indicates that the Circular Vertical Hall Built-In Self-Test (CVHST) failed.

Bit	Value	Description
3	0	Error condition not present
	1	Error condition present



## CTRL (Control) Register

Address: 0x08

Address	0x08							
Bit	7	6	5	4	3	2	1	0
Name	–	–	–	STST	TRST	RPM	PWR	ERST
R/W	–	–	–	RW1C	RW1C	R/W	R/W	RW1C
Value	X	X	X	X	0/1	0/1	0/1	0/1
Reset	0	0	0	0	0	0	0	0

Initialization and operation configuration control command settings.

RW1C: When a 1 is written to the field, the command is immediately executed, and the value returns to zero. When Reading the field, this type of field will always read back 0.

### STS [4] Self-Test Start

Commands the A1337/8 to begin Self Test.

Bit	Value	Description
4	0	Does not trigger Self-Test
	1	Self-Test is triggered based on pre-selected options in the "U_INIT_ST" field of EEPROM

### PWR [1] Low Power Mode Select (A1337 only)

Determines operational mode at power-on reset. Determines whether device goes into standard Low Power mode or into Transport mode on next low power cycle request.

Bit	Value	Description
1	0	Low Power Mode
	1	Transport Mode

### TRST [3] Turns Count Reset (A1337 only)

Commands the A1337 to clear the value in the TRN register (0x02).

Bit	Value	Description
3	0	Turns counter reset
	1	Turns counter not reset

### ERST [0] Error Flags Reset

A feature to clear the values in the ERR register (0x04).

Bit	Value	Description
0	0	ERR register not cleared
	1	ERR register cleared

### RPM [2] RPM Operating Mode (see Programming Manual)

This field is populated on power-up by the EEPROM field RPMD.

This field can be written during operation to temporarily override the EEPROM. On the next power cycle, this field will reset to the value determined by the EEPROM field RPMD. This bit must be a '1' to enable internal averaging.

Bit	Value	Description
2	0	Internal Averaging not allowed
	1	Internal Averaging allowed

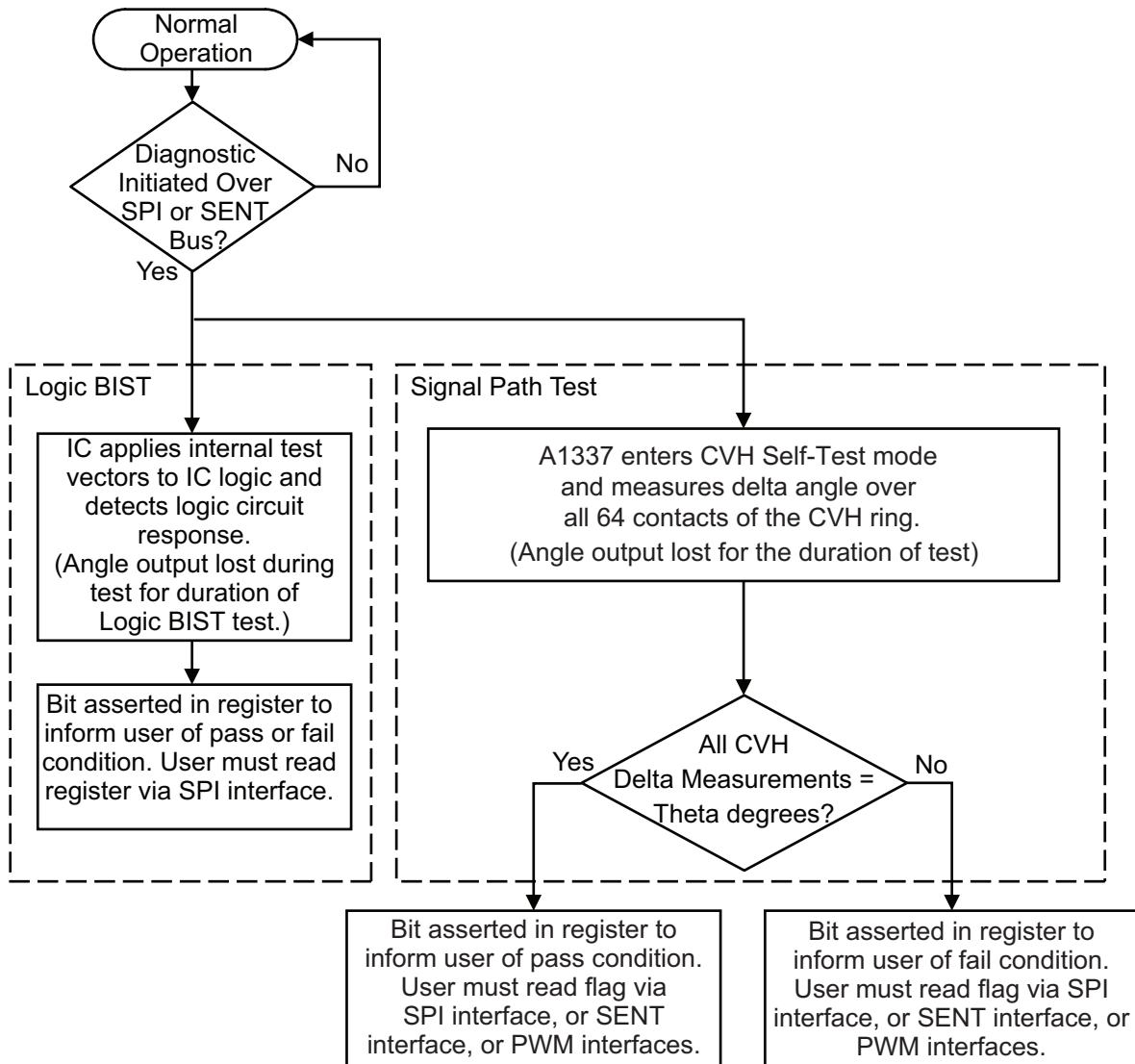


Figure 10: User-Interface Diagnostic Diagram

## APPLICATION INFORMATION

### Serial Interface Description

The A1337 features SPI, SENT, and PWM interfaces. The following figures show some typical application circuits for using the A1337 with these interfaces.

### Calculating Target Zero-Degree Angle

When shipped from the factory, the default angle value when oriented as shown in Figure 11, is approximately 21° (201° on the second die). In some cases, the end user may want to program an angle offset in the A1337 to compensate for variation in magnetic assemblies, or for applications where absolute system level readings are required.

The internal algorithm for computing the output angle is as follows:

$$Angle_{OUT} = Angle_{RAW} - Reference\ Angle \quad (3)$$

The procedure to “zero out” the A1337 is quite simple. During final application calibration and programming, position

the magnet above the A1337 in the required zero-degree position, and read the angle from the A1337 using the SPI interface ( $Angle_{OUT}$ ). From this angle, the Reference Angle required to program the A1337 can be computed as follows:

$$Reference\ Angle = Angle_{OUT} \quad (4)$$

### Bypass Pins Usage

The Bypass pins are required for proper operation of the device. A 0.1  $\mu$ F capacitor should be placed in very close proximity to each of the bypass pins.

When using the SPI communication protocol, the A1337 has the ability to support host micro-controllers inputs with Voltage Input High ( $V_{IH}$ ) thresholds of 2 V (minimum). This option only requires BYP1 to be populated with a 0.1  $\mu$ F capacitor.

By using an optional second Bypass capacitor on the BYP2 pins, the A1337 can also support host micro-controllers inputs with Voltage Input High ( $V_{IH}$ ) thresholds of 2.5 V (minimum). This

- Target alignment for default angle setting
- Target rotation axis intersects primary die
  - Sets primary die 21° default point
  - Sets secondary die 201° default point
- (Example shows element E1 as primary die element E2 as secondary die)

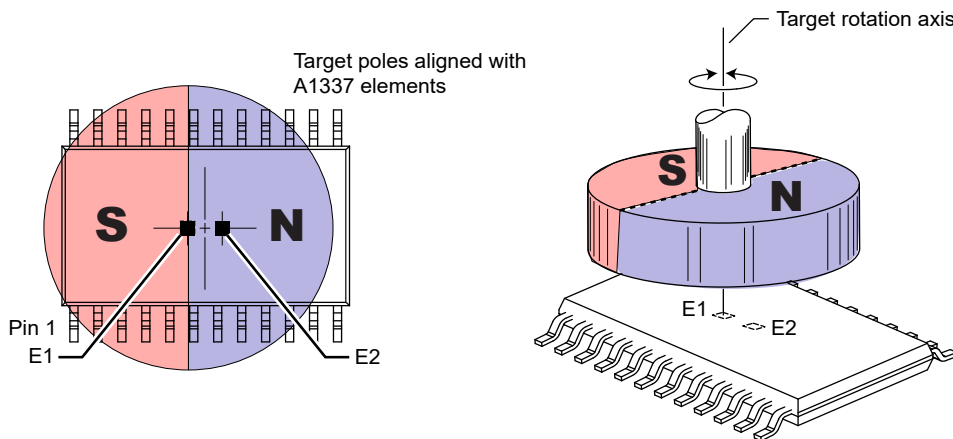


Figure 11: Orientation of Magnet Relative to Primary and Secondary Die

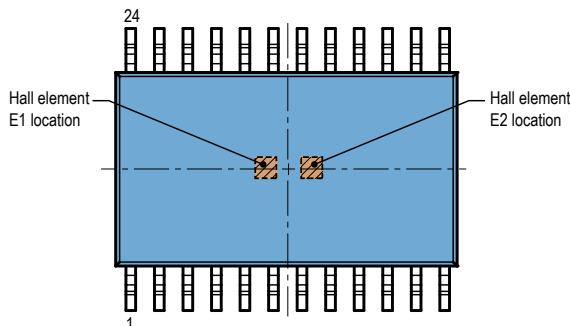


Figure 12: Hall Element Located Off-Center within the Device Body

(refer to the Package Outline Drawing for reference dimensions)

option requires that both BYP1 and BYP2 pins be populated with 0.1  $\mu$ F capacitors, and that the appropriate EEPROM configuration bit be enabled. Contact Allegro for availability of parts with elevated SPI output levels.

The Bypass pins are not intended to be used to source external components. To assist with PCB layout, please see the Operating Characteristics table for output voltage and current requirements.

## Changing Sampling Modes

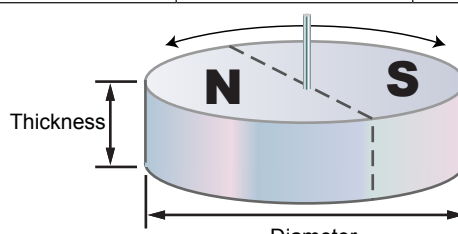
The A1337 features a High RPM sampling mode, and a Low RPM sampling mode. The default power-on state of the A1337 is loaded from EEPROM. To configure the A1337 to Low RPM mode, set the Operating mode to Low RPM mode by writing a logic 1 to bit 2 (RPM) of the configuration commands (CTRL) register, via the SPI interface.

## Magnetic Target Requirements

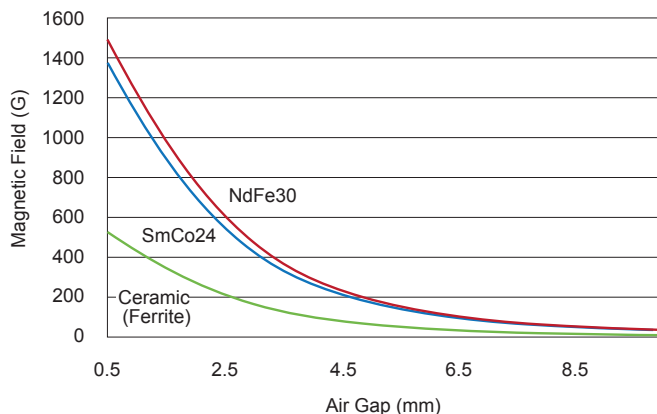
The A1337 is designed to operate with magnets constructed with a variety of magnetic materials, cylindrical geometries, and field strengths, as shown in Table 9. Contact Allegro for more detailed information on magnet selection and theoretical error.

**Table 9: Target Magnet Parameters**

Magnetic Material	Diameter (mm)	Thickness (mm)
Neodymium (bonded)	15	4
Neodymium (sintered)*	10	2.5
Neodymium (sintered)	8	3
Neodymium / SmCo	6	2.5

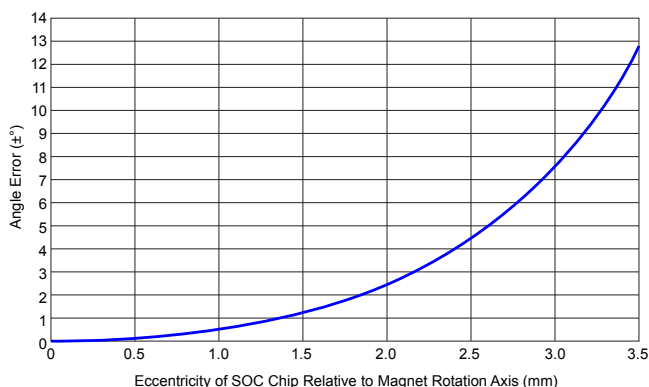


\*A sintered Neodymium magnet with 10 mm (or greater) diameter and 2.5 mm thickness is the recommended magnet for redundant applications.



**Figure 13: Magnetic Field versus Air Gap for a magnet 6 mm in diameter and 2.5 mm thick.**

Allegro can provide similar curves for customer application magnets upon request. We recommend larger magnets for applications that require optimized accuracy performance.



**Figure 14: Angle Error versus Eccentricity**

## Redundant Applications and Alignment Error

The A1337 is designed to be used in redundant, on-axis, applications with a single magnet spinning over the two separate dice that are mounted side-by-side in the same package. One challenge with this configuration is correctly lining up the magnet with the device package, so it is important to be aware of the physical separation of the two dice.

Figure 15 illustrates the behavior of alignment error when using a  $\varnothing 10 \text{ mm} \times 2.5 \text{ mm}$  Neodymium magnet that is located 2.7 mm above the branded face of the package. The curve shows the relationship between absolute angle error present on the output of the die versus eccentricity of the die relative to the rotation axis of the magnet. The curve is the same for both dice in the package.

The curve provides guidance to determine what the optimal magnet placement should be for a given application. For example, given that the maximum spacing between the two dice is 1 mm, if the center of the magnet rotation is placed at the midpoint between the two dice, each die will have a maximum eccentricity of 0.5 mm.

For applications with reduced accuracy requirements, considering one die the primary and the other die the secondary, the magnet axis of rotation could be positioned directly above the primary die, and thus offset 1 mm from the secondary die, yielding zero alignment error on the primary die, and approximately  $\pm 1^\circ$  of error on the secondary die, relative to the primary die, due to geometric mismatch.

## System Timing and Error

The A1337 is a digital system, and therefore takes angle samples at a fixed sampling rate. When using a sensing device with a fixed sampling rate to sample a continuously moving target, there will be error introduced that can be simply calculated with the sampling rate of the device and the speed at which the magnetic signal is changing. In the case of the A1337, the input signal is rotating at various speeds, and the sampling rate of the A1337 is fixed at ANG. The calculation would be:

$$ANG (\mu s) \times \text{angular velocity } (^\circ/\mu s) \quad (5)$$

So the faster the magnetic object is spinning, the further behind in angle the output signal will seem for a fixed sampling rate.

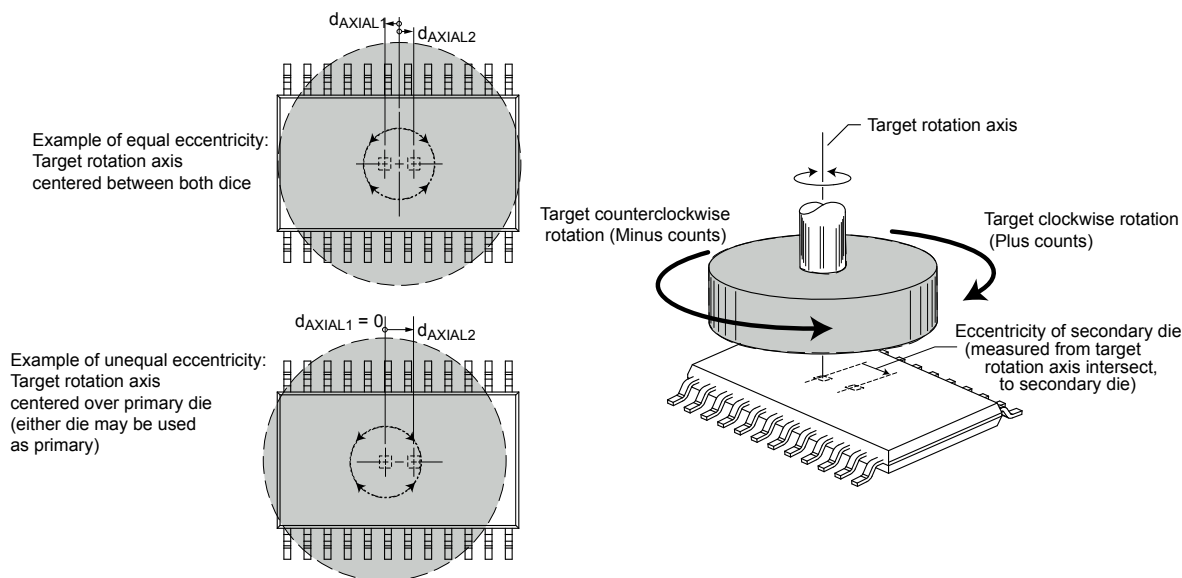


Figure 15: Demonstration of Magnet to Sensing Element Eccentricity

## CHARACTERISTIC PERFORMANCE DATA

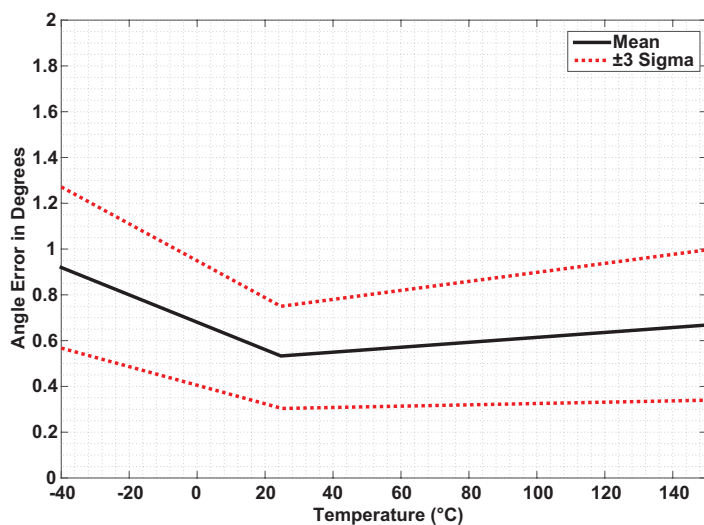


Figure 16: Angle Error over Temperature (300 G)

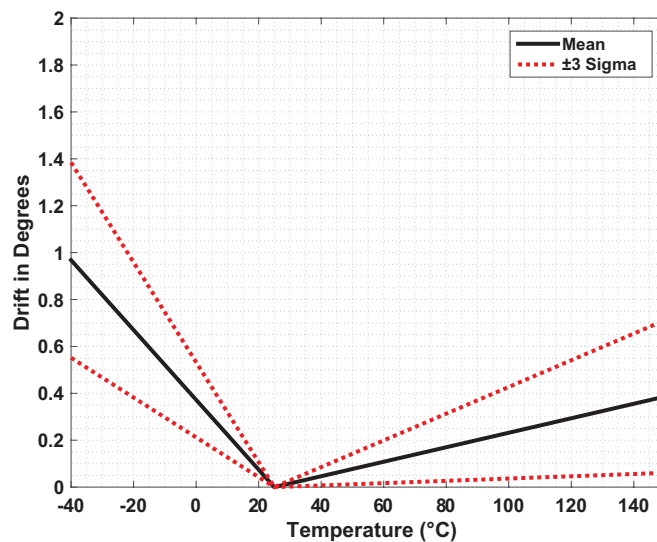


Figure 17: Angle Drift Relative to 25°C (300 G)

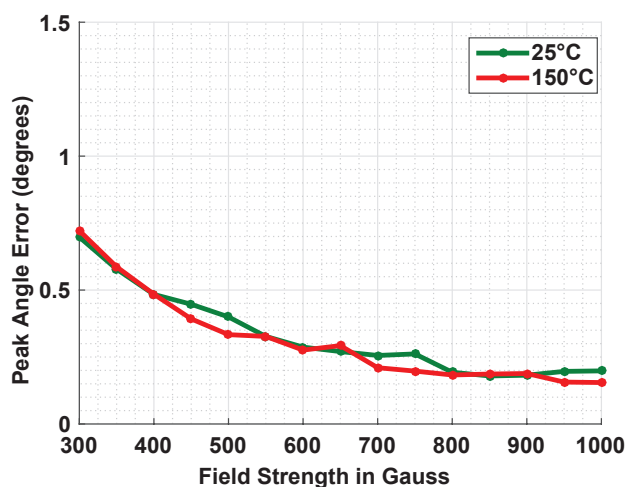
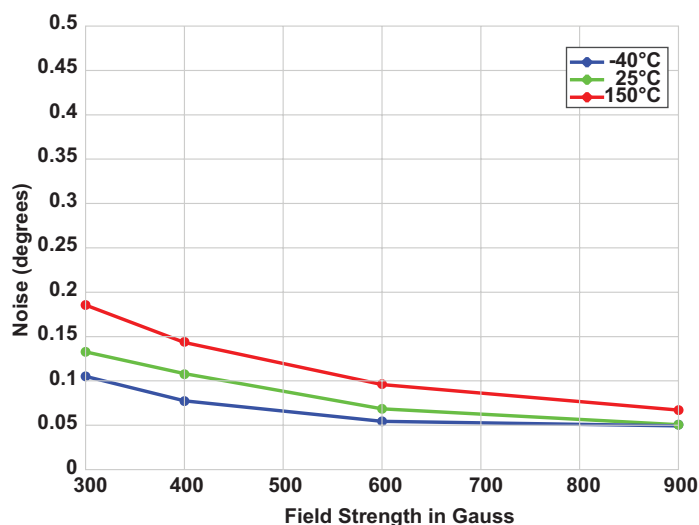


Figure 18: Angle Error over Field Strength

Figure 19: Typical One Sigma Angle Noise  
Over Field Strength

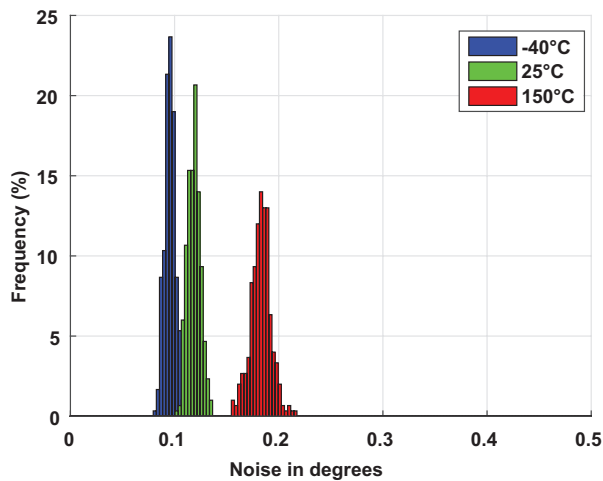


Figure 20: Noise Distribution over Temperature  
(1  $\sigma$ , 300 G)

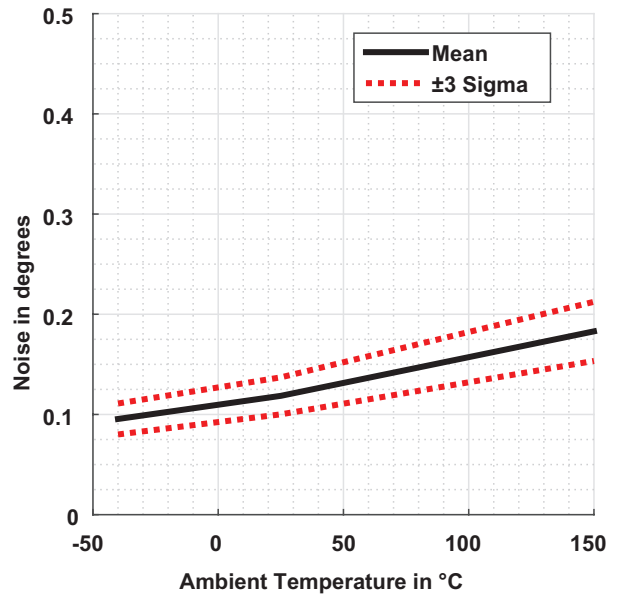


Figure 21: Noise Performance over Temperature  
(1  $\sigma$ , 300 G)

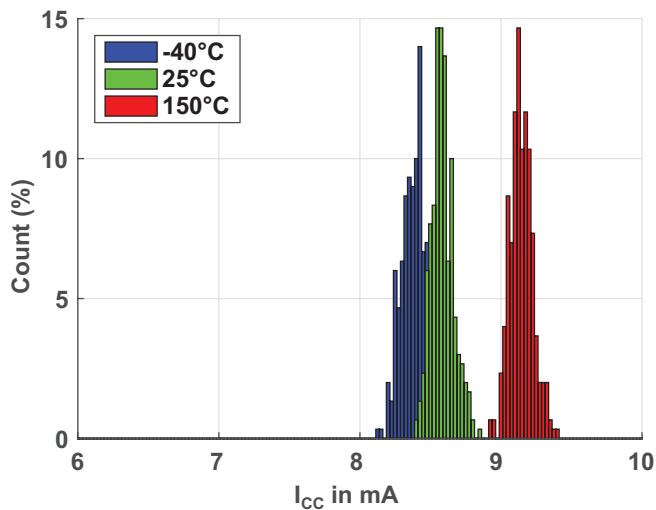


Figure 22:  $I_{CC}$  Distribution over Temperature  
( $I_{CC}$  per die,  $V_{CC} = 3.7$  V)

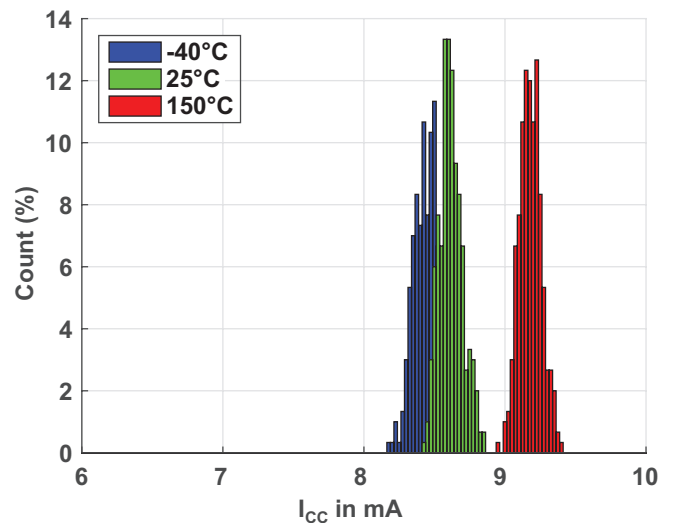
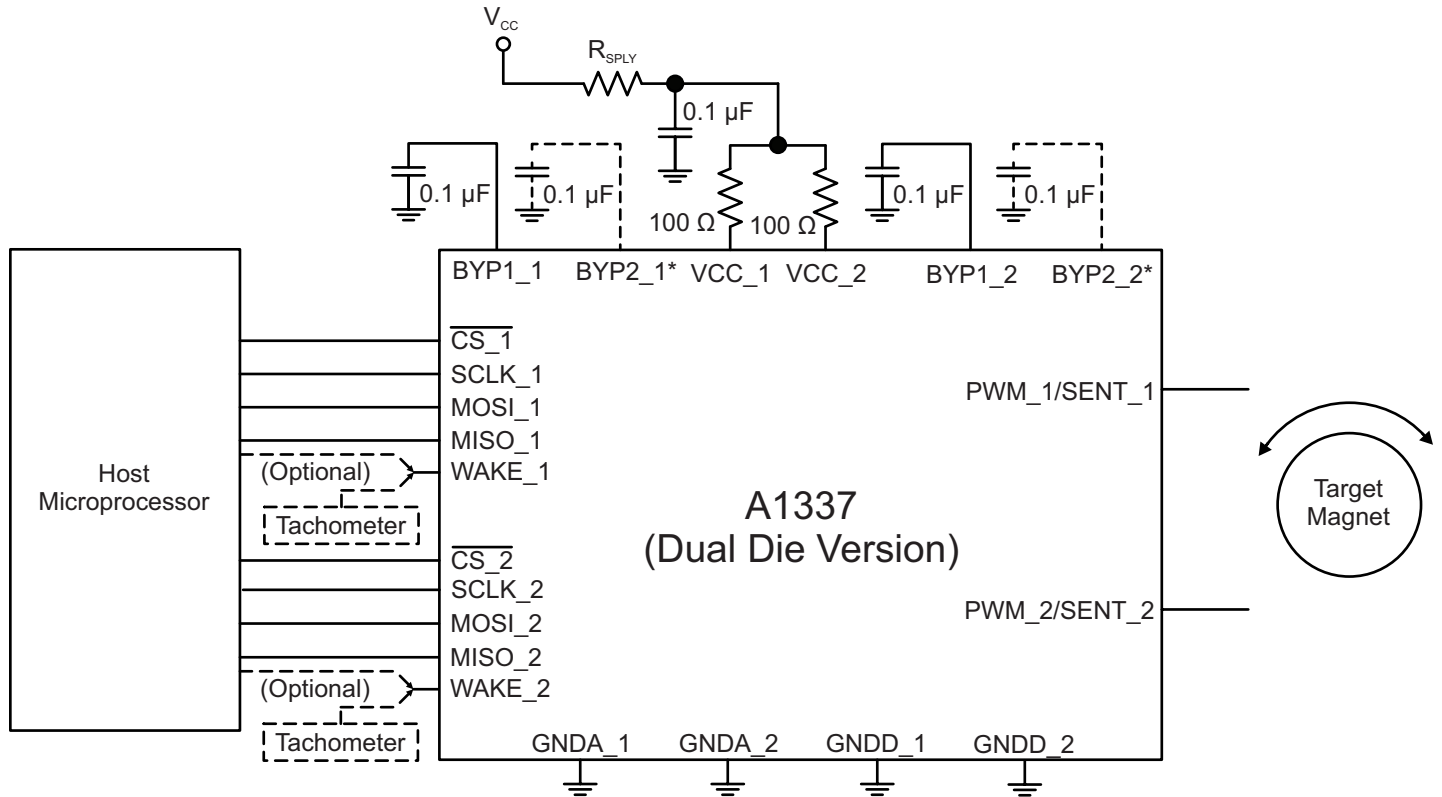


Figure 23:  $I_{CC}$  Distribution over Temperature  
( $I_{CC}$  per die,  $V_{CC} = 16$  V)

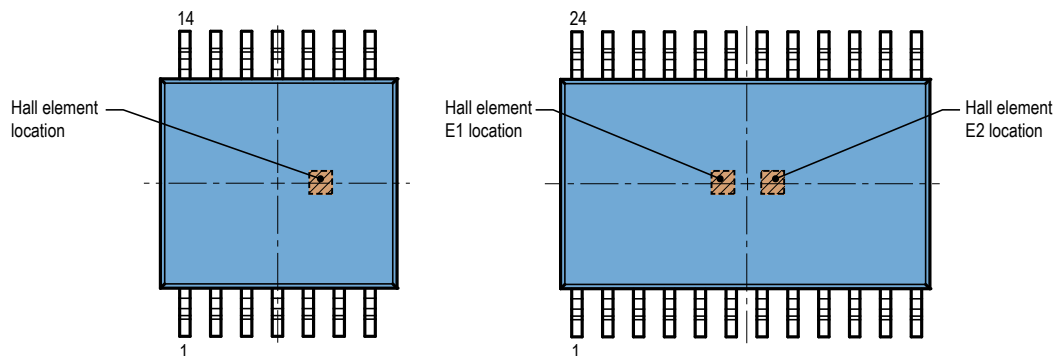
## EMC Reduction

For applications with stringent EMC requirements, a 100  $\Omega$  resistance should be added to the supply for the device in order to suppress noise. A recommended circuit is shown in Figure 24.



**Figure 24: Typical application diagram (dual-die version) with EMC suppression resistor,  $R_{SPLY}$ , on supply line.**

\*Secondary bypass capacitors only required when using Elevated SPI Output Voltage. Contact Allegro for availability.



**Figure 25: Hall element located off-center within the device body; refer to the Package Outline Drawing for reference dimensions**



## PACKAGE OUTLINE DRAWINGS

### For Reference Only – Not for Tooling Use

(Reference MO-153 AB-1)

Dimensions in millimeters

Dimensions exclusive of mold flash, gate burrs, and dambar protrusions  
Exact case and lead configuration at supplier discretion within limits shown

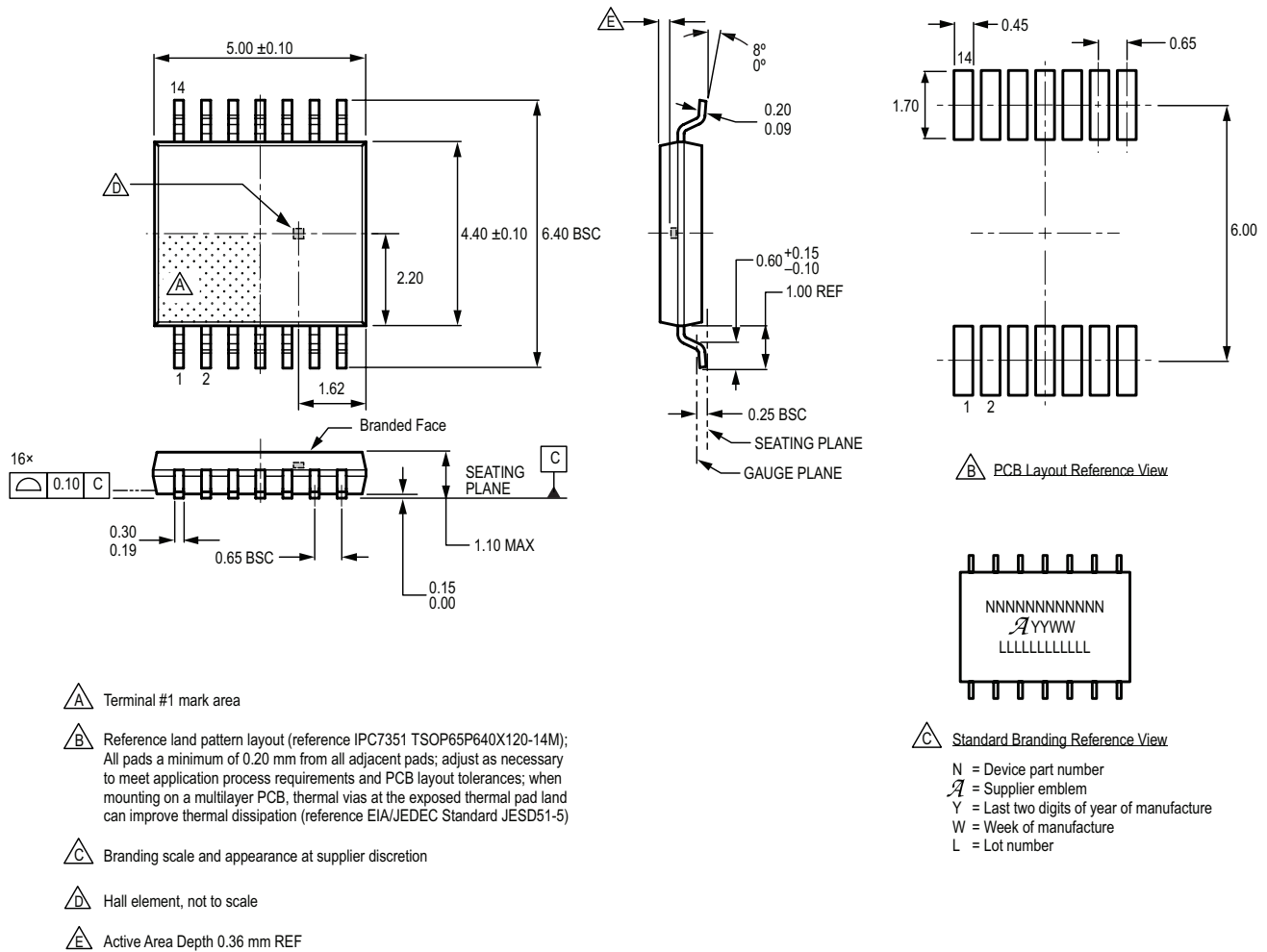


Figure 26: Package LE, 14-Pin TSSOP

## For Reference Only – Not for Tooling Use

(Reference MO-153 AD)  
Dimensions in millimeters  
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions  
Exact case and lead configuration at supplier discretion within limits shown

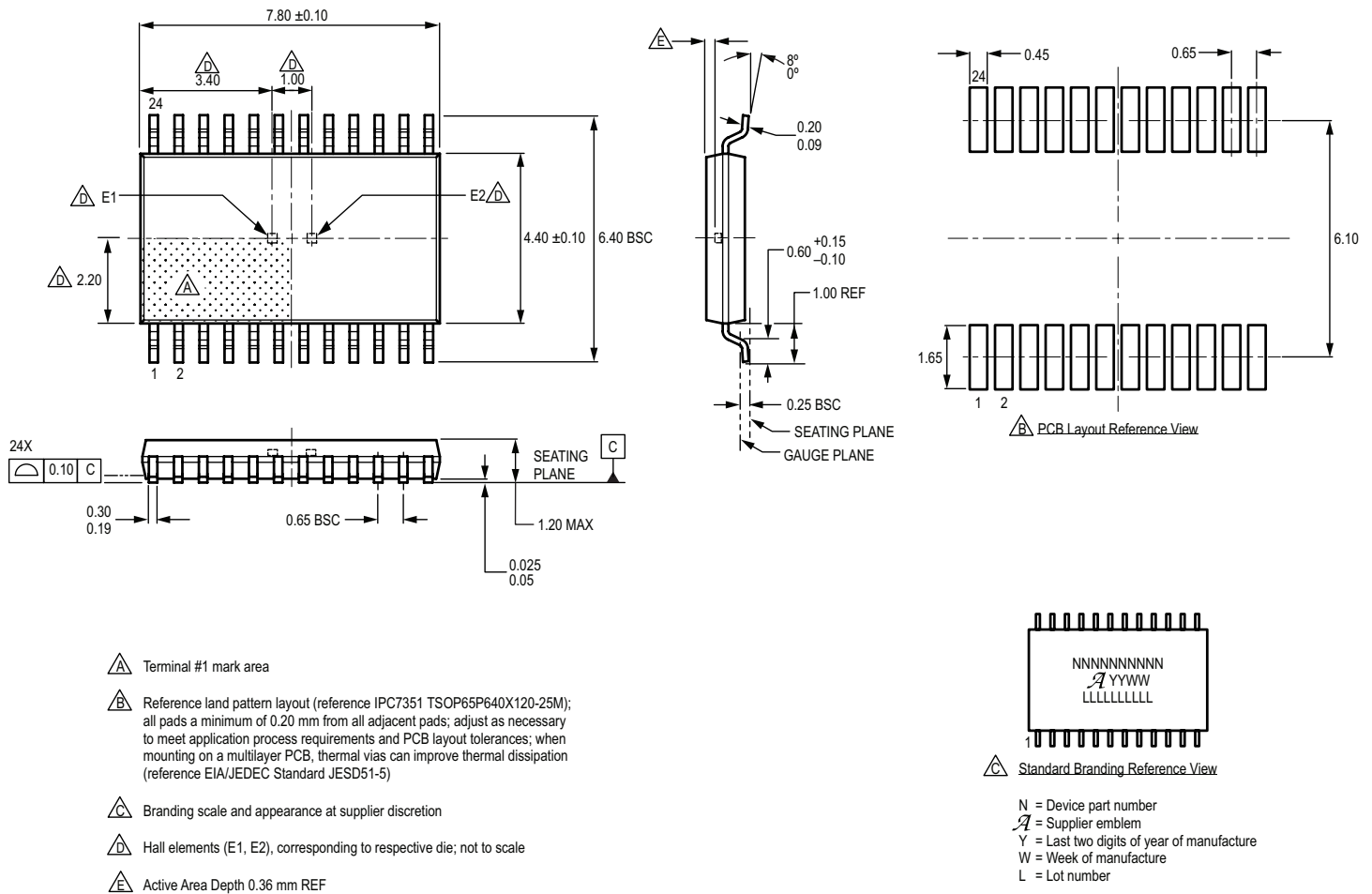


Figure 27: Package LE, 24-Pin TSSOP

## Revision History

Number	Date	Description
–	November 18, 2016	Initial release
1	May 26, 2017	Overall editorial update
2	July 14, 2017	Updated Figure 14
3	January 24, 2018	Updated Typical Application Diagram (page 4); Low-Power Mode Average Supply Current test conditions and Bypass2 Pin Output Voltage characteristic and test conditions (page 7); PWM Carrier Frequency test conditions, Sent Output Signal maximum value, Logical BIST Coverage versus Time (page 8); Sleep State Period test conditions (page 9); Effective Resolution typical value, footnotes 8-15 (page 10); Overview, Angle Measurement sections (page 11-12); Table 2 (page 15); Manchester Code Low Voltage maximum value (page 18); Table 5 (page 21); Table 6 (page 22); CTRL Register, STS Self-Test Start (page 25); Calculating Target Zero-Degree Angle (page 27); and Figure 23 (page 32).

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